TEXAS INSTRUMENTS
LM25118
JAJSDG8F – JULY 2011 – REVISED MARCH 2018

LM25118 電圧範囲の広い昇降圧コントローラ

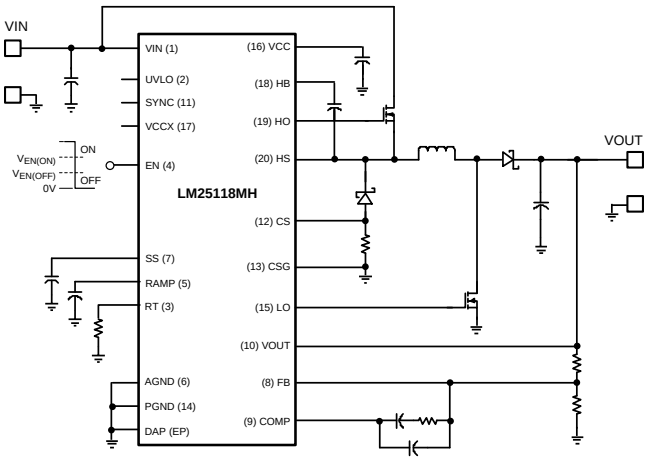
1 特長

- 入力動作電圧範囲: 3V～42V
- エミュレーションによるピーク電流モード制御
- 降圧と昇圧のモード間をスムーズに遷移
- スイッチング周波数を最高500kHzにプログラム可能
- 発振器の同期機能
- 高電圧バイアス・レギュレータを内蔵
- ハイサイドおよびローサイドのゲート・ドライバを内蔵
- ソフトスタート時間をプログラム可能
- 非常に低いシャットダウン電流
- イネーブル入力
- 広帯域幅のエラー・アンプ
- 1.5%のフィードバック・リファレンス精度
- サーマル・シャットダウン
- パッケージ: 20ピンのHTSSOP (露出パッド)
- WEBENCH® Power Designerにより、LM25118を使用するカスタム設計を作成

2 アプリケーション

産業用昇降圧電源

概略回路図



3 概要

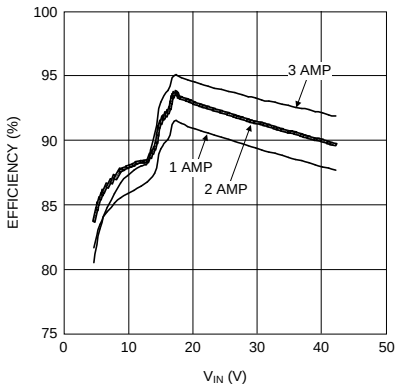
LM25118は広い電圧範囲で動作する昇降圧スイッチング・レギュレータ・コントローラで、最小限の外付け部品で高性能かつコスト効率が高い昇降圧レギュレータを実装するために必要なすべての機能が搭載されています。昇降圧トポロジにより、入力電圧が出力電圧より低くても高くても、出力電圧のレギュレーションが維持されるため、車載用アプリケーションには特に適しています。LM25118は、入力電圧がレギュレートされる出力電圧よりも十分に高いときは降圧レギュレータとして動作し、入力電圧が出力に近付くと、次第に昇降圧モードへ移行します。このデュアル・モード方式により、広い範囲の入力電圧においてレギュレーションが維持され、降圧モードで最適な変換効率を実現し、モード遷移の間も出力にグリッチが発生しません。この使いやすいコントローラには、ハイサイド降圧MOSFETと、ローサイド昇圧MOSFET用のドライバが含まれています。レギュレータの制御方式は、エミュレートされた電流ランプを使用する電流モード制御に基づいています。エミュレートされた電流モード制御を使用することで、パルス幅変調回路のノイズ感受性が低下し、入力電圧の高いアプリケーションに必要な、非常に小さいデューティ・サイクルを高い信頼性で制御できます。さらに、電流制限、サーマル・シャットダウン、イネーブル入力の保護機能が搭載されています。このデバイスは、放熱を助ける露出ダイ接続パッドを備えて消費可能電力を増大させた、20ピンHTSSOPパッケージで供給されます。

製品情報(1)

型番	パッケージ	本体サイズ(公称)
LM25118	HTSSOP (20)	6.50mm×4.40mm

(1) 提供されているすべてのパッケージについては、巻末の注文情報を参照してください。

効率とV_{IN}およびI_{OUT}との関係、V_{OUT} = 12V



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4 改訂履歴

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Revision E (July 2017) から Revision F に変更 **Page**

- Deleted roque text from ESD Ratings table. ... 6

Revision D (August 2014) から Revision E に変更 **Page**

- 車載用デバイスを独立したデータシート(SNVSAX7)へ移動 ... 1
- WEBENCHリスト項目の言語を変更、データシートにWEBENCHのコンテンツとリンクを追加 ... 1
- Moved the storage temp parameters to the *Absolute Maximum Ratings* ... 6
- Changed junction temperature range from: ±150°C max to: –40°C to 150°C ... 6
- Changed *Handling Ratings* table to *ESD Ratings* ... 6
- Moved the junction temperature ranges in the *Electrical Characteristics* table to the test conditions statement ... 7
- Removed the V_{OLL} minimum value ... 8
- Removed the V_{OLH} minimum value ... 8
- 「コミュニティ・リソース」セクションを追加 ... 36

Revision C (Novemeber 2013) から Revision D に変更 **Page**

- 新しいTIの標準に合わせてデータシートのフローとレイアウトを変更。「製品情報」表、「アプリケーションと実装」セクション、「電源に関する推奨事項」セクション、「レイアウト」セクション、「デバイスおよびドキュメントのサポート」セクション、「メカニカル、パッケージ、および注文情報」セクションを追加して 変更 ... 1
- Changed Removed footnote to "VCC, LO, VCCX, UVLO to GND" ... 6

Revision B (April, 2013) から Revision C に変更 **Page**

- Deleted V_{IN} Range on Functional Block Diagram ... 12
- Changed Figure 19 ... 24
- Changed VIN Specification ... 24
- Changed L1 Buck Mode Value ... 26

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- Changed $I_{RIPPLE(BUCK)}$ Value 26
- Changed Inductor Selection – L1 Text 26
- Changed Equation 16 26
- Changed Equation 17 26
- Added Efficiency Parameter 26
- Changed $I_{1(PEAK)}$Value 27
- Changed $I_{2(PEAK)}$ Value 27
- Changed R13 = R_{SENSE} Text 27
- Added Equation 20 27
- Added Equation 21 27
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- Changed $R13_{(BUCK)}$ Value 27
- Changed $R13_{(BUCK-BOOST)}$ Value 27
- Added Inductor Current Limit Calculation Section 28
- Added Equation 29 28
- Added Equation 31 28
- Changed Equation 34 28
- Changed ESR_{MAX} Value 28
- Deleted Previous Equation 17 28
- Deleted Previous Equation 18 28
- Changed C1 – C5 = Input Capacitors Text 29
- Changed R8, R9 Text 30
- Changed R1, R3, C21 Text 30
- Changed Equation 45 30
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- Changed D_{MIN} to D_{MAX} in Equation 47 31
- Changed D_{MAX} Value 31
- Changed DC $Gain_{(MOD)}$ Value 31
- Changed ESR_{ZERO} Value 31
- Changed R4, C18, C17 Text 32
- Changed Figure 21 33
- Changed Figure 22 33
- Changed Figure 23 33
- Added Figure 24 33
- Added Figure 25 33
- Added Figure 26 33

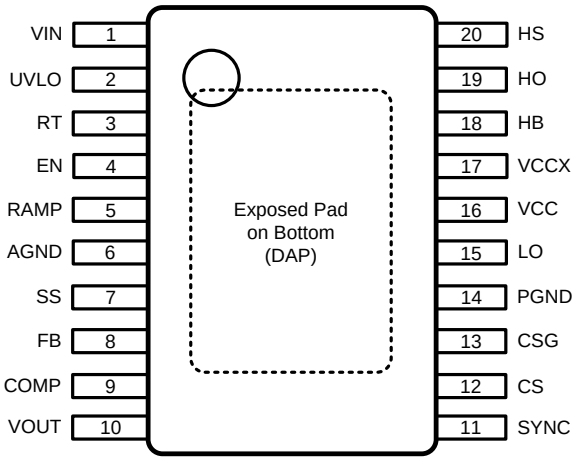
Revision A (March 2013) から Revision B に変更 **Page**

- Changed layout of National Data Sheet to TI format 24

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5 Pin Configuration and Functions

PWP Package
20-Pin HTSSOP With Exposed Pad
Top View



Pin Functions

PIN		TYPE	DESCRIPTION
NO.	NAME		
1	VIN	P/I	Input supply voltage.
2	UVLO	I	If the UVLO pin is below 1.23 V, the regulator will be in standby mode (VCC regulator running, switching regulator disabled). When the UVLO pin exceeds 1.23 V, the regulator enters the normal operating mode. An external voltage divider can be used to set an undervoltage shutdown threshold. A fixed 5-µA current is sourced out of the UVLO pin. If a current limit condition exists for 256 consecutive switching cycles, an internal switch pulls the UVLO pin to ground and then releases.
3	RT	I	The internal oscillator frequency is set with a single resistor between this pin and the AGND pin. The recommended frequency range is 50 kHz to 500 kHz.
4	EN	I	If the EN pin is below 0.5 V, the regulator will be in a low power state drawing less than 10 µA from VIN. EN must be raised above 3 V for normal operation.
5	RAMP	I	Ramp control signal. An external capacitor connected between this pin and the AGND pin sets the ramp slope used for emulated current mode control.
6	AGND	G	Analog ground.
7	SS	I	Soft-Start. An external capacitor and an internal 10-µA current source set the rise time of the error amp reference. The SS pin is held low when VCC is less than the VCC undervoltage threshold (< 3.7 V), when the UVLO pin is low (< 1.23 V), when EN is low (< 0.5 V) or when thermal shutdown is active.
8	FB	I	Feedback signal from the regulated output. Connect to the inverting input of the internal error amplifier.
9	COMP	O	Output of the internal error amplifier. The loop compensation network should be connected between COMP and the FB pin.
10	VOUT	I	Output voltage monitor for emulated current mode control. Connect this pin directly to the regulated output.
11	SYNC	I	Sync input for switching regulator synchronization to an external clock.
12	CS	I	Current sense input. Connect to the diode side of the current sense resistor.
13	CSG	I	Current sense ground input. Connect to the ground side of the current sense resistor.
14	PGND	G	Power Ground.
15	LO	O	Boost MOSFET gate drive output. Connect to the gate of the external boost MOSFET.
16	VCC	P/I/O	Output of the bias regulator. Locally decouple to PGND using a low ESR/ESL capacitor located as close to the controller as possible.

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Pin Functions (continued)

PIN		TYPE	DESCRIPTION
NO.	NAME		
17	VCCX	P/I	Optional input for an externally supplied bias supply. If the voltage at the VCCX pin is greater than 3.9 V, the internal VCC regulator is disabled and the VCC pin is internally connected to VCCX pin supply. If VCCX is not used, connect to AGND.
18	HB	I	High-side gate driver supply used in bootstrap operation. The bootstrap capacitor supplies current to charge the high-side MOSFET gate. This capacitor should be placed as close to the controller as possible and connected between HB and HS.
19	HO	O	Buck MOSFET gate drive output. Connect to the gate of the high side buck MOSFET through a short, low inductance path.
20	HS	I	Buck MOSFET source pin. Connect to the source terminal of the high-side buck MOSFET and the bootstrap capacitor.
—	EP	—	Exposed thermal pad. Solder to the ground plane under the IC to aid in heat dissipation.

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6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

	MIN	MAX	UNIT
VIN, EN, VOUT to GND	–0.3	45	V
VCC, LO, VCCX, UVLO to GND	–0.3	16	V
HB to HS	–0.3	16	V
HO to HS	–0.3	HB + 0.3	V
HS to GND	–4	45	V
CSG, CS to GND	–0.3	0.3	V
RAMP, SS, COMP, FB, SYNC, RT to GND	–0.3	7	V
Junction temperature	–40	150	°C
Storage temperature, T_{stg}	–55	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

		VALUE	UNIT
$V_{(ESD)}$ Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±2000	V
	Charged-device model (CDM), per JEDEC specification JESD22-C101(2)	±1000	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

	MIN	MAX	UNIT
VIN(2)	3	42	V
VCC, VCCX	4.75	14	V
Junction temperature	–40	+125	°C

(1) Functional operation of the device and/or non-degradation at the Absolute Maximum Ratings or other conditions beyond those indicated in the Recommended Operating Conditions is not implied. Operating Range conditions indicate the conditions at which the device is functional and the device should not be operated beyond such conditions. For ensured specifications and conditions, see *Electrical Characteristics*.
(2) VIN ≥ 5.0 V is required to initially start the controller.

6.4 Thermal Information

THERMAL METRIC(1)		LM25118 PWP (HTSSOP) 20 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	110(2)	°C/W
		40(3)	
		35(4)	
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	4	°C/W

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report.
(2) JEDEC 2-Layer test board (JESD 51-3)
(3) JEDEC 4-Layer test board (JESD 51-7) with 4 thermal vias under the Exposed Pad
(4) JEDEC 4-Layer test board (JESD 51-7) with 12 thermal vias under the Exposed Pad

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6.5 Electrical Characteristics

Unless otherwise specified, the following conditions apply: VIN = 24 V, VCCX = 0 V, EN = 5 V, RT = 29.11 kΩ, no load on LO and HO. Typical values apply for T_J = 25°C; minimum and maximum values apply over the full junction temperature range for operation: −40°C to +125°C.(1)(1)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
VIN SUPPLY						
I_{BIAS}	VIN operating current	VCCX = 0 V		4.5	5.5	mA
I_{BIASX}	VIN operating current	VCCX = 5 V		1	1.85	mA
I_{STDBY}	VIN shutdown current	EN = 0 V		1	10	µA
VCC REGULATOR						
$V_{CC(REG)}$	VCC regulation	VCCX = 0 V	6.8	7	7.2	V
$V_{CC(REG)}$	VCC regulation	VCCX = 0 V, VIN = 6 V	5	5.25	5.5	V
	VCC sourcing current limit	VCC = 0	21	35		mA
	VCCX switch threshold	VCCX rising	3.68	3.85	4.02	V
	VCCX switch hysterisis			0.2		V
	VCCX switch RDS(ON)	ICCX = 10 mA		5	12	Ω
	VCCX switch leakage	VCCX = 0 V		0.5	1	µA
	VCCCX pulldown resistance	VCCX = 3 V		70		kΩ
	VCC undervoltage lockout voltage	VCC rising	3.52	3.7	3.86	V
	VCC undervoltage hysterisis			0.21		V
	HB DC bias current	HB-HS = 15 V		205	260	µA
	VC LDO mode turnoff			10		V
EN INPUT						
$V_{EN(OFF)}$	EN input low threshold	V_{EN} falling			0.5	V
$V_{EN(ON)}$	EN input high threshold	V_{EN} rising	3			V
	EN input bias current	V_{EN} = 3 V	–1		1	µA
	EN input bias current	V_{EN} = 0.5 V	–1		1	µA
	EN input bias current	V_{EN} = 42 V		50		µA
UVLO THRESHOLDS						
UVLO	UVLO standby threshold	UVLO Rising	1.191	1.231	1.271	V
ΔUVLO	UVLO threshold hysteresis			0.105		V
	UVLO pullup current source	UVLO = 0 V		5		µA
	UVLO pulldown $R_{DS(ON)}$			100	200	Ω

(1) Minimum and Maximum limits are ensured through test, design, or statistical correlation. Typical values represent the most likely parametric norm at T_J = 25°C, and are provided for reference purposes only.

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Electrical Characteristics (continued)

Unless otherwise specified, the following conditions apply: VIN = 24 V, VCCX = 0 V, EN = 5 V, RT = 29.11 kΩ, no load on LO and HO. Typical values apply for T_J = 25°C; minimum and maximum values apply over the full junction temperature range for operation: −40°C to +125°C.(1)(1)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SOFT START						
	SS current source	SS = 0 V	7.5	10.5	13.5	µA
	SS to FB offset	FB = 1.23 V		150		mV
	SS output low voltage	Sinking 100 µA, UVLO = 0 V		7		mV
ERROR AMPLIFIER						
V_{REF}	FB reference voltage	Measured at FB pin, FB = COMP	1.212	1.23	1.248	V
	FB input bias current	FB = 2 V		20	200	nA
	COMP sink/source current		3			mA
A_{OL}	DC gain			80		dB
f_{BW}	Unity bain bandwidth			3		MHz
PWM COMPARATORS						
$t_{HO(OFF)}$	Forced HO off-time		305	400	495	ns
$T_{ON(MIN)}$	Minimum HO on-time			70		ns
	COMP to comparator offset			200		mV
OSCILLATOR (RT PIN)						
f_{SW1}	Frequency 1	RT = 29.11 kΩ	178	200	224	kHz
f_{SW2}	Frequency 2	RT = 9.525 kΩ	450	515	575	kHz
SYNC						
	Sync threshold falling			1.3		V
CURRENT LIMIT						
$V_{CS(TH)}$	Cycle-by-cycle sense voltage threshold (CS-CSG)	RAMP = 0 buck mode	–103	–125	–147	mV
$V_{CS(THX)}$	Cycle-by-cycle sense voltage threshold (CS-CSG)	RAMP = 0 buck-boost mode	–218	–255	–300	mV
	CS bias current	CS = 0 V		45	60	µA
	CSG bias current	CSG = 0 V		45	60	µA
	Current limit fault timer			256		cycles
RAMP GENERATOR						
I_{R2}	RAMP current 2	VIN = 12 V, VOUT = 12 V	95	115	135	µA
I_{R3}	RAMP current 3	VIN = 5 V, VOUT = 12 V	65	80	95	µA
	VOUT bias current	VOUT = 42 V		245		µA
LOW-SIDE (LO) GATE DRIVER						
V_{OLL}	LO low-state output voltage	I_{LO} = 100 mA		0.14	0.23	V
V_{OHL}	LO high-state output voltage	I_{LO} = –100 mA $V_{OHL} = V_{CC}-V_{LO}$		0.25		V
	LO rise time	C-load = 1 nF, VCC = 8 V		16		ns
	LO fall time	C-load = 1 nF, VCC = 8 V		14		ns
I_{OHL}	Peak LO source current	V_{LO} = 0 V, VCC = 8 V		2.2		A
I_{OLL}	Peak LO sink current	V_{LO} = VCC = 8 V		2.7		A
HIGH-SIDE (HO) GATE DRIVER						
V_{OLH}	HO low-state output voltage	I_{HO} = 100 mA		0.135	0.21	V
V_{OHH}	HO high-state output voltage	I_{HO} = –100 mA, $V_{OHH} = V_{HB}-V_{OH}$		0.25		V

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Electrical Characteristics (continued)

Unless otherwise specified, the following conditions apply: VIN = 24 V, VCCX = 0 V, EN = 5 V, RT = 29.11 kΩ, no load on LO and HO. Typical values apply for T_J = 25°C; minimum and maximum values apply over the full junction temperature range for operation: −40°C to +125°C.(1)(1)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
	HO rise time	C-load = 1 nF, VCC = 8 V		14		ns
	HO fall time	C-load = 1 nF, VCC = 8 V		12		ns
I_{OHH}	Peak HO source current	V_{HO} = 0 V, VCC = 8 V		2.2		A
I_{OLH}	Peak HO sink current	V_{HO} = VCC = 8 V		3.5		A
	HB-HS undervoltage lockout			3		V
BUCK-BOOST CHARACTERISTICS(2)						
	Buck-boost mode	Buck duty cycle	69%	75%	80%	
THERMAL						
T_{SD}	Thermal shutdown junction temperature			165		°C
ΔT_{SD}	Thermal shutdown hysterisis			25		°C

(2) When the duty cycle exceeds 75%, the LM25118 controller gradually phases into the Buck-Boost mode.

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6.6 Typical Characteristics

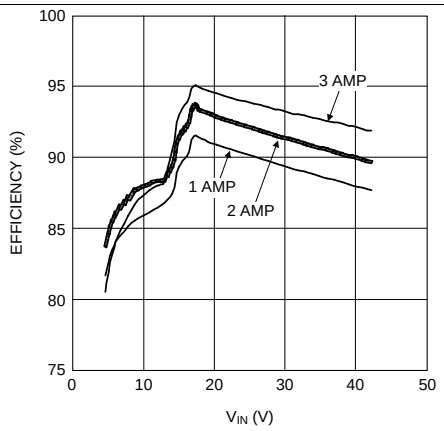


Figure 1. Efficiency vs VIN and IOUT VOUT = 12 V

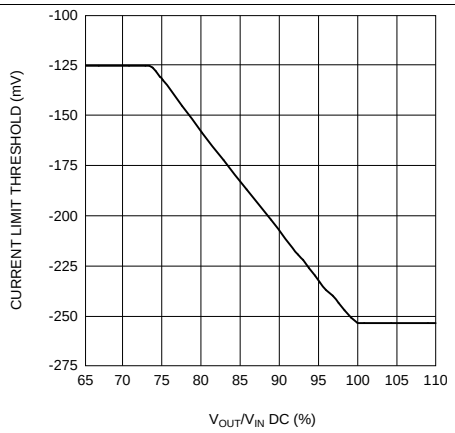


Figure 2. Current Limit Threshold vs VOUT/VIN VOUT = 12 V

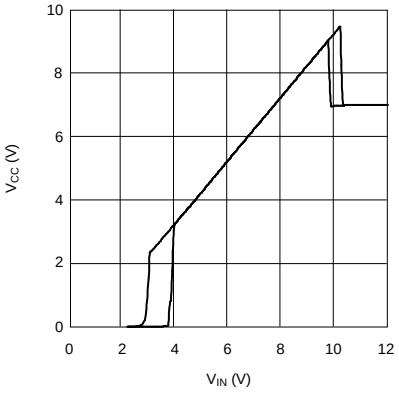


Figure 3. VCC vs VIN

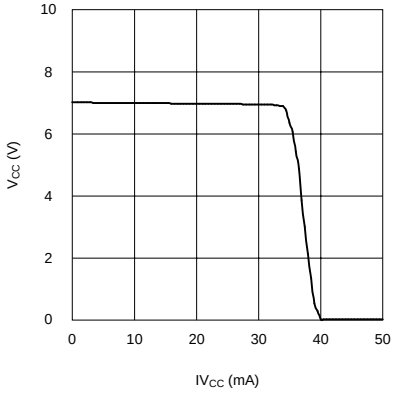


Figure 4. VCC vs IVCC

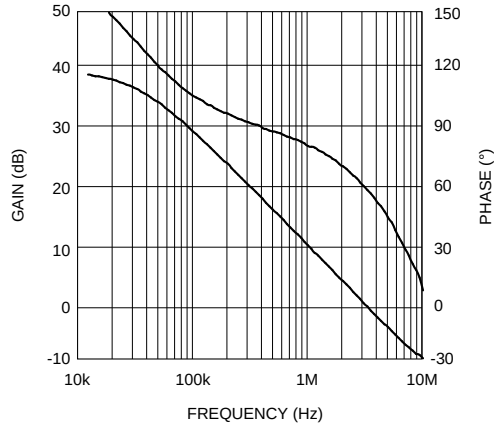


Figure 5. Error Amplifier Gain/Phase

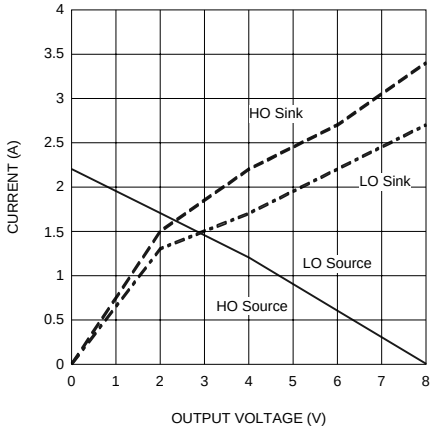


Figure 6. LO and HO Peak Gate Current vs Output Voltage VCC = 8 V

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Typical Characteristics (continued)

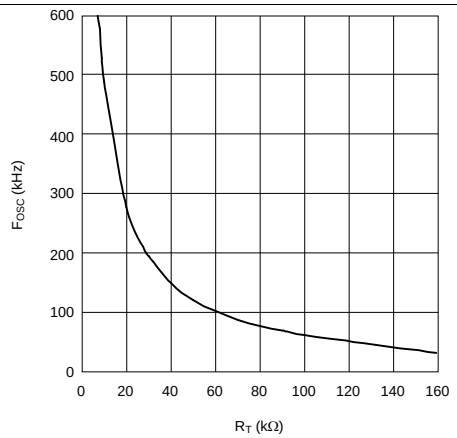


Figure 7. Oscillator Frequency vs RT

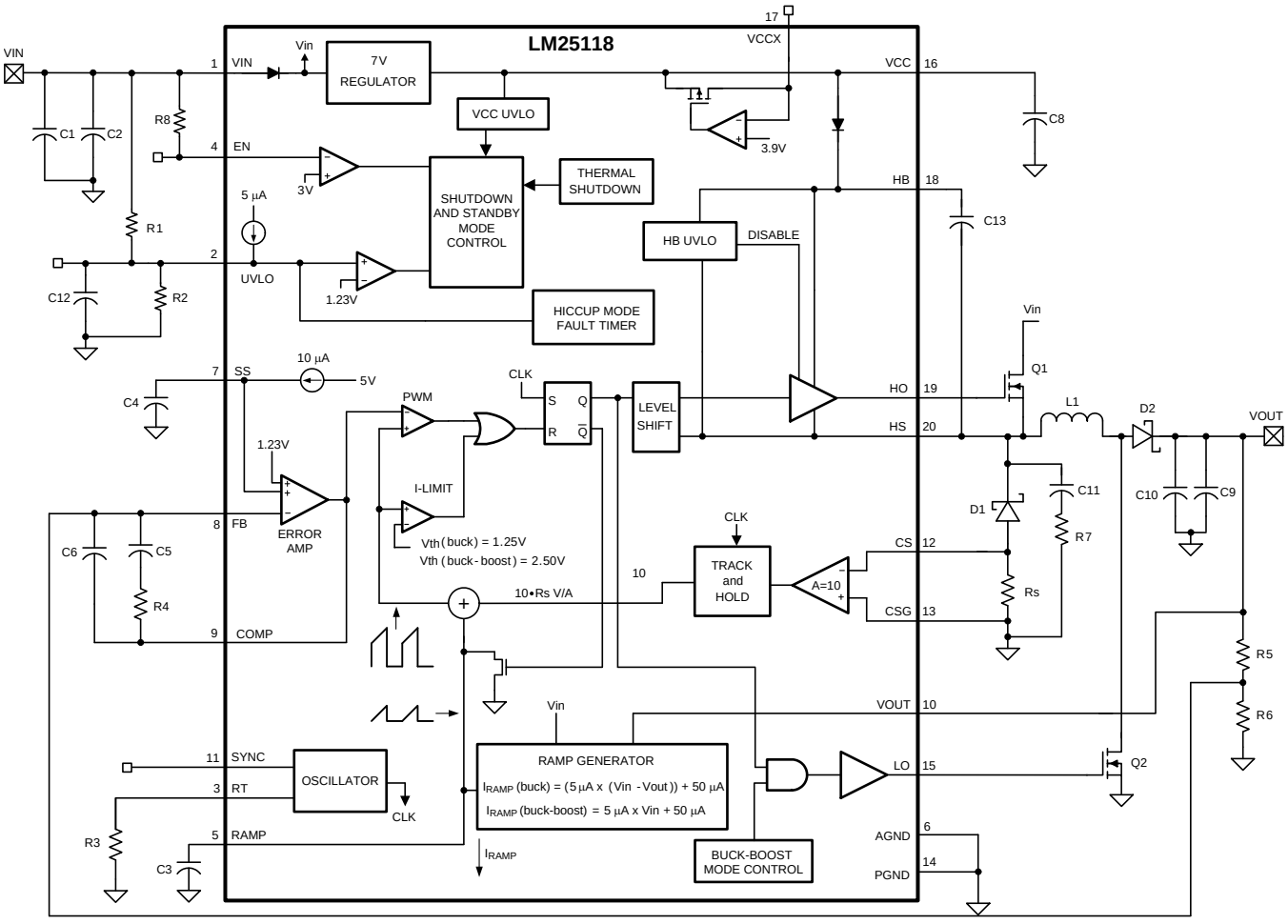
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7 Detailed Description

7.1 Overview

The LM25118 high voltage switching regulator features all of the functions necessary to implement an efficient high voltage buck or buck-boost regulator using a minimum of external components. The regulator switches smoothly from buck to buck-boost operation as the input voltage approaches the output voltage, allowing operation with the input greater than or less than the output voltage. This easy-to-use regulator integrates high-side and low-side MOSFET drivers capable of supplying peak currents of 2 A. The regulator control method is based on current mode control using an emulated current ramp. Peak current mode control provides inherent line feedforward, cycle-by-cycle current limiting and ease-of-loop compensation. The use of an emulated control ramp reduces noise sensitivity of the pulse-width modulation circuit, allowing reliable processing of very small duty cycles necessary in high input voltage applications. The operating frequency is user programmable from 50 kHz to 500 kHz. An oscillator synchronization pin allows multiple LM25118 regulators to self synchronize or be synchronized to an external clock. Fault protection features include current limiting, thermal shutdown, and remote shutdown capability. An undervoltage lockout input allows regulator shutdown when the input voltage is below a user selected threshold, and a low state at the enable pin will put the regulator into an extremely low current shutdown state. The device is available in the 20-pin HTSSOP package featuring an exposed pad to aid in thermal dissipation.

7.2 Functional Block Diagram



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7.3 Feature Description

A buck-boost regulator can maintain regulation for input voltages either higher or lower than the output voltage. The challenge is that buck-boost power converters are not as efficient as buck regulators. The LM25118 has been designed as a dual-mode controller whereby the power converter acts as a buck regulator while the input voltage is above the output. As the input voltage approaches the output voltage, a gradual transition to the buck-boost mode occurs. The dual mode approach maintains regulation over a wide range of input voltages, while maintaining the optimal conversion efficiency in the normal buck mode. The gradual transition between modes eliminates disturbances at the output during transitions. Figure 8 shows the basic operation of the LM25118 regulator in the buck mode. In buck mode, transistor Q1 is active and Q2 is disabled. The inductor current ramps in proportion to the Vin – Vout voltage difference when Q1 is active and ramps down through the recirculating diode D1 when Q1 is off. The first order buck mode transfer function is VOUT/VIN = D, where D is the duty cycle of the buck switch, Q1.

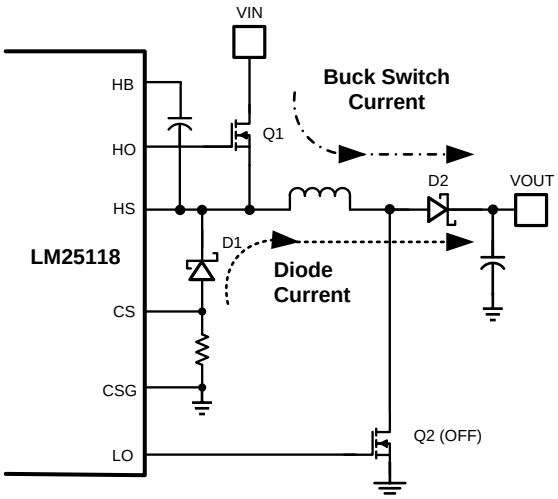


Figure 8. Buck Mode Operation

Feature Description (continued)

Figure 9 shows the basic operation of buck-boost mode. In buck-boost mode, both Q1 and Q2 are active for the same time interval each cycle. The inductor current ramps up (proportional to VIN) when Q1 and Q2 are active and ramps down through the recirculating diode during the off-time. The first order buck-boost transfer function is VOUT/VIN = D/(1 – D), where D is the duty cycle of Q1 and Q2.

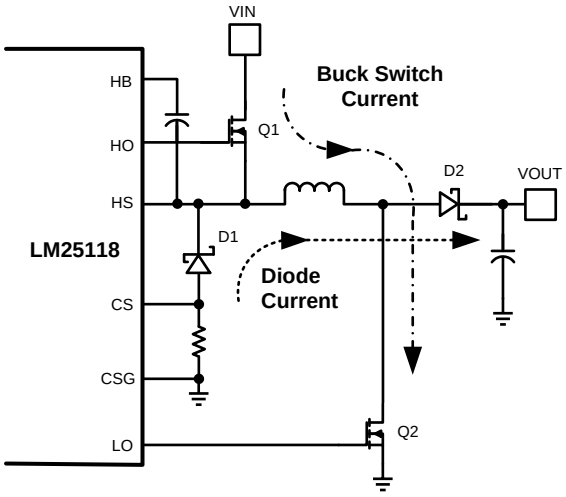


Figure 9. Buck-Boost Mode Operation

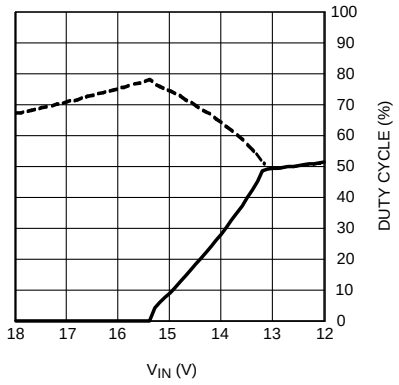


Figure 10. Mode Dependence on Duty Cycle (VOUT =12 V)

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Feature Description (continued)

7.3.1 UVLO

An undervoltage lockout pin is provided to disable the regulator when the input is below the desired operating range. If the UVLO pin is below 1.13 V, the regulator enters a standby mode with the outputs disabled, but with VCC regulator operating. If the UVLO input exceeds 1.23 V, the regulator will resume normal operation. A voltage divider from the input to ground can be used to set a VIN threshold to disable the regulator in brownout conditions or for low input faults.

If a current limit fault exists for more than 256 clock cycles, the regulator will enter a *hiccup* mode of current limiting and the UVLO pin will be pulled low by an internal switch. This switch turns off when the UVLO pin approaches ground potential allowing the UVLO pin to rise. A capacitor connected to the UVLO pin will delay the return to a normal operating level and thereby set the off-time of the hiccup mode fault protection. An internal 5-µA pullup current pulls the UVLO pin to a high state to ensure normal operation when the VIN UVLO function is not required and the pin is left floating.

7.3.2 Oscillator and Sync Capability

The LM25118 oscillator frequency is set by a single external resistor connected between the RT pin and the AGND pin. The R_T resistor should be located very close to the device and connected directly to the pins of the IC. To set a desired oscillator frequency (f), the necessary value for the R_T resistor can be calculated from Equation 1:

$$R_T = \frac{6.4 \times 10^9}{f} - 3.02 \times 10^3 \quad (1)$$

The SYNC pin can be used to synchronize the internal oscillator to an external clock. The external clock must be of higher frequency than the free-running frequency set by the R_T resistor. A clock circuit with an open-drain output is the recommended interface from the external clock to the SYNC pin. The clock pulse duration should be greater than 15 ns.

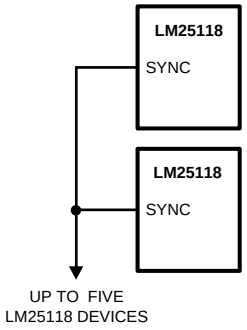


Figure 11. Sync From Multiple Devices

Multiple LM25118 devices can be synchronized together simply by connecting the SYNC pins together. In this configuration, all of the devices will be synchronized to the highest frequency device. The diagram in Figure 11 shows the SYNC input and output features of the LM25118. The internal oscillator circuit drives the SYNC pin with a strong pulldown and weak pullup inverter. When the SYNC pin is pulled low, either by the internal oscillator or an external clock, the ramp cycle of the oscillator is terminated and forced 400 ns off-time is initiated before a new oscillator cycle begins. If the SYNC pins of several LM25118 ICs are connected together, the IC with the highest internal clock frequency will pull all the connected SYNC pins low and terminate the oscillator ramp cycles of the other ICs. The LM25118 with the highest programmed clock frequency will serve as the master and control the switching frequency of all the devices with lower oscillator frequencies.

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Feature Description (continued)

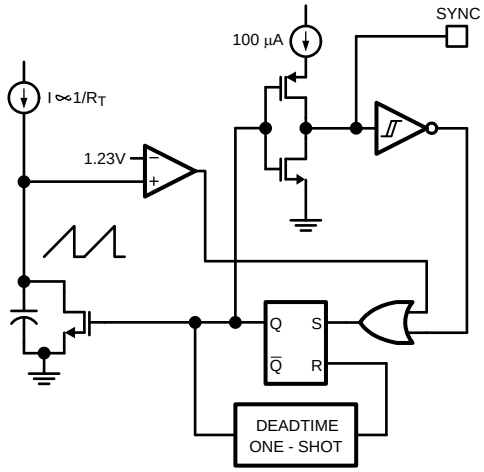


Figure 12. Simplified Oscillator and Block Diagram With Sync I/O Circuit

7.3.3 Error Amplifier and PWM Comparator

The internal high gain error amplifier generates an error signal proportional to the difference between the regulated output voltage and an internal precision reference (1.23 V). The output of the error amplifier is connected to the COMP pin. Loop compensation components, typically a type II network shown in Figure 18 are connected between the COMP and FB pins. This network creates a low-frequency pole, a zero, and a noise reducing high-frequency pole. The PWM comparator compares the emulated current sense signal from the RAMP generator to the error amplifier output voltage at the COMP pin. The same error amplifier is used for operation in buck and buck-boost mode.

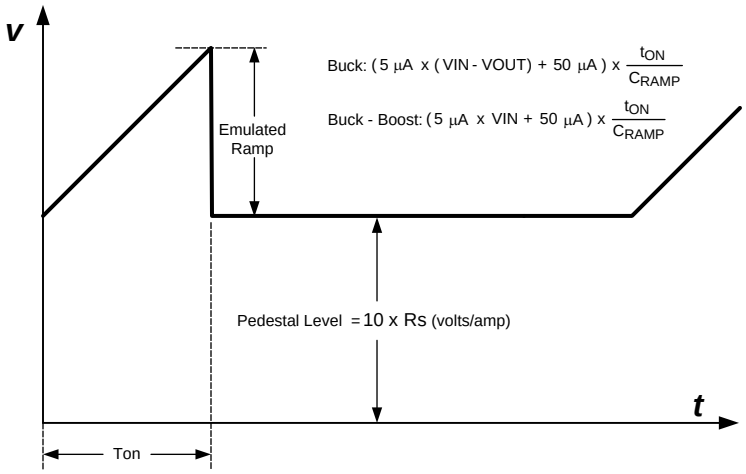


Figure 13. Composition of Emulated Current Signal

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Feature Description (continued)

7.3.4 Ramp Generator

The ramp signal of a pulse-width modulator with current mode control is typically derived directly from the buck switch drain current. This switch current corresponds to the positive slope portion of the inductor current signal. Using this signal for the PWM ramp simplifies the control loop transfer function to a single pole response and provides inherent input voltage feed-forward compensation. The disadvantage of using the buck switch current signal for PWM control is the large leading edge spike due to circuit parasitics. The leading edge spike must be filtered or blanked to avoid early termination of the PWM pulse. Also, the current measurement may introduce significant propagation delays. The filtering, blanking time, and propagation delay limit the minimal achievable pulse width. In applications where the input voltage may be relatively large in comparison to the output voltage, controlling a small pulse width is necessary for regulation. The LM25118 uses a unique ramp generator which does not actually measure the buck switch current but instead creates a signal representing or emulating the inductor current. The emulated ramp provides signal to the PWM comparator that is free of leading edge spikes and measurement or filtering delays. The current reconstruction is comprised of two elements: a sample-and-hold pedestal level and a ramp capacitor that is charged by a controlled current source. See Figure 13 for details.

The sample-and-hold pedestal level is derived from a measurement of the recirculating current through a current sense resistor in series with the recirculating diode of the buck regulator stage. A small value current-sensing resistor is required between the recirculating diode anode and ground. The CS and CSG pins should be Kelvin connected directly to the sense resistor. The voltage level across the sense resistor is sampled and held just prior to the onset of the next conduction interval of the buck switch. The current sensing and sample-and-hold provide the DC level of the reconstructed current signal. The sample and hold of the recirculating diode current is valid for both buck and buck-boost modes. The positive slope inductor current ramp is emulated by an external capacitor connected from the RAMP pin to the AGND and an internal voltage controlled current source. In buck mode, the ramp current source that emulates the inductor current is a function of the VIN and VOUT voltages per Equation 2.

$$I_{RAMP}\ (buck) = \frac{5\ \mu A}{V} \times (VIN - VOUT) + 50\ \mu A \tag{2}$$

In buck-boost mode, the ramp current source is a function of the input voltage VIN, per Equation 3.

$$I_{RAMP}\ (buck - boost) = \frac{5\ \mu A}{V} \times VIN + 50\ \mu A \tag{3}$$

Proper selection of the RAMP capacitor (C_{RAMP}) depends upon the value of the output inductor (L) and the current sense resistor (R_S). For proper current emulation, the sample and hold pedestal value and the ramp amplitude must have the same relative relationship to the actual inductor current. That is:

$$R_S \times A = \frac{g_m \times L}{C_{RAMP}}$$

$$C_{RAMP} = \frac{g_m \times L}{A \times R_S} \tag{4}$$

where

- g_m is the ramp generator transconductance (5 µA/V)
- A is the current sense amplifier gain (10 V/V)

The ramp capacitor should be located very close to the device and connected directly to the RAMP and AGND pins.

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Feature Description (continued)

The relationship between the average inductor current and the pedestal value of the sampled inductor current can cause instability in certain operating conditions. This instability is known as sub-harmonic oscillation, which occurs when the inductor ripple current does not return to its initial value by the start of the next switching cycle. Sub-harmonic oscillation is normally characterized by observing alternating wide and narrow pulses at the switch node. Adding a fixed slope voltage ramp (slope compensation) to the current sense signal prevents this oscillation. The 50 µA of offset current provided from the emulated current source adds enough slope compensation to the ramp signal for output voltages less than or equal to 12 V. For higher output voltages, additional slope compensation may be required. In such applications, the ramp capacitor can be decreased from the nominal calculated value to increase the ramp slope compensation.

The pedestal current sample is obtained from the current sense resistor (Rs) connected to the CS and CSG pins. It is sometimes helpful to adjust the internal current sense amplifier gain (A) to a lower value to obtain the higher current limit threshold. Adding a pair of external resistors RG in a series with CS and CSG as shown in Figure 14 reduces the current sense amplifier gain A according to Equation 5.

$$A = \frac{10k}{1k + R_G} \tag{5}$$

7.3.5 Current Limit

In the buck mode the average inductor current is equal to the output current (Iout). In buck-boost mode the average inductor current is approximately equal to:

$$Iout \times \left(1 + \frac{VOUT}{VIN}\right) \tag{6}$$

Consequently, the inductor current in buck-boost mode is much larger especially when VOUT is large relative to VIN. The LM25118 provides a current monitoring scheme to protect the circuit from possible overcurrent conditions. When set correctly, the emulated current sense signal is proportional to the buck switch current with a scale factor determined by the current sense resistor. The emulated ramp signal is applied to the current limit comparator. If the peak of the emulated ramp signal exceeds 1.25 V when operating in the buck mode, the PWM cycle is immediately terminated (cycle-by-cycle current limiting). In buck-boost mode the current limit threshold is increased to 2.50 V to allow higher peak inductor current. To further protect the external switches during prolonged overload conditions, an internal counter detects consecutive cycles of current limiting. If the counter detects 256 consecutive current limited PWM cycles, the LM25118 enters a low power dissipation hiccup mode. In the hiccup mode, the output drivers are disabled, the UVLO pin is momentarily pulled low, and the soft-start capacitor is discharged. The regulator is restarted with a normal soft-start sequence once the UVLO pin charges back to 1.23 V. The hiccup mode off-time can be programmed by an external capacitor connected from UVLO pin to ground. This hiccup cycle will repeat until the output overload condition is removed.

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Feature Description (continued)

In applications with low output inductance and high input voltage, the switch current may overshoot due to the propagation delay of the current limit comparator and control circuitry. If an overshoot should occur, the sample-and-hold circuit will detect the excess recirculating diode current. If the sample-and-hold pedestal level exceeds the internal current limit threshold, the buck switch will be disabled and will skip PWM cycles until the inductor current has decayed below the current limit threshold. This approach prevents current runaway conditions due to propagation delays or inductor saturation since the inductor current is forced to decay before the buck switch is turned on again.

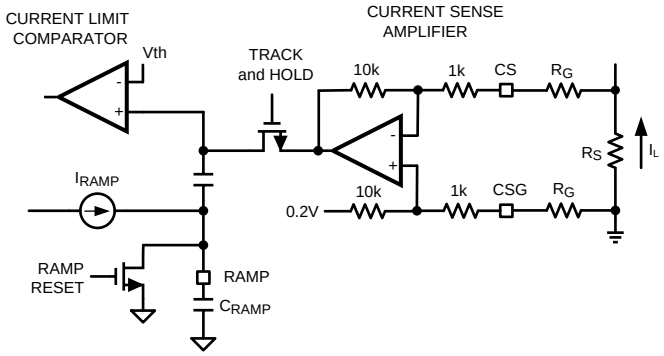


Figure 14. Current Limit and Ramp Circuit

7.3.6 Maximum Duty Cycle

Each conduction cycle of the buck switch is followed by a forced minimum off-time of 400 ns to allow sufficient time for the recirculating diode current to be sampled. This forced off-time limits the maximum duty cycle of the controller. The actual maximum duty cycle will vary with the operating frequency of Equation 7.

$$D_{MAX} = 1 - f \times 400 \times 10^{-9} \quad (7)$$

where

- f is the oscillator frequency in Hz

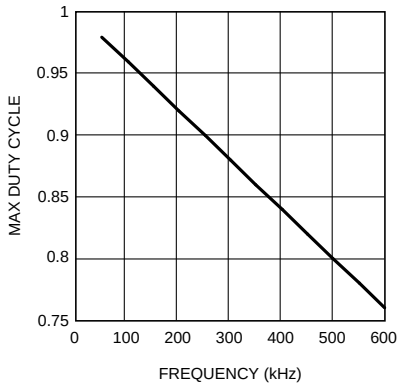


Figure 15. Maximum Duty Cycle vs Frequency

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Feature Description (continued)

Limiting the maximum duty cycle will limit the maximum boost ratio (VOUT/VIN) while operating in buck-boost mode. For example, from Figure 15, at an operating frequency of 500 kHz, D_{MAX} is 80%. Using the buck-boost transfer function.

$$D = \frac{Vout}{Vin + Vout} \tag{8}$$

with

- D = 80%, solving for VOUT results in
- VOUT = 4 × VIN

With a minimum input voltage of 5 V, the maximum possible output voltage is 20 V at f = 500 kHz. The buck-boost step-up ratio can be increased by reducing the operating frequency which increases the maximum duty cycle.

7.3.7 Soft Start

The soft-start feature allows the regulator to gradually reach the initial steady-state operating point, thus reducing start-up stresses and surges. The internal 10-µA soft-start current source gradually charges an external soft-start capacitor connected to the SS pin. The SS pin is connected to the positive input of the internal error amplifier. The error amplifier controls the pulse-width modulator such that the FB pin approximately equals the SS pin as the SS capacitor is charged. Once the SS pin voltage exceeds the internal 1.23-V reference voltage, the error amp is controlled by the reference instead of the SS pin. The SS pin voltage is clamped by an internal amplifier at a level of 150 mV above the FB pin voltage. This feature provides a soft-start controlled recovery in the event a severe overload pulls the output voltage (and FB pin) well below normal regulation but doesn't persist for 256 clock cycles.

Various sequencing and tracking schemes can be implemented using external circuits that limit or clamp the voltage level of the SS pin. The SS pin acts as a noninverting input to the error amplifier anytime SS voltage is less than the 1.23-V reference. In the event a fault is detected (overtemperature, VCC undervoltage, hiccup current limit), the soft-start capacitor will be discharged. When the fault condition is no longer present, a new soft-start sequence will begin.

7.3.8 HO Output

The LM25118 contains a high-side, high-current gate driver and associated high voltage level shift. This gate driver circuit works in conjunction with an internal diode and an external bootstrap capacitor. A 0.1-µF ceramic capacitor, connected with short traces between the HB pin and HS pin is recommended for most circuit configurations. The size of the bootstrap capacitor depends on the gate charge of the external FET. During the off-time of the buck switch, the HS pin voltage is approximately –0.5 V and the bootstrap capacitor is charged from VCC through the internal bootstrap diode. When operating with a high PWM duty cycle, the buck switch will be forced off each cycle for 400 ns to ensure that the bootstrap capacitor is recharged.

7.3.9 Thermal Protection

Internal Thermal Shutdown circuitry is provided to protect the integrated circuit in the event the maximum junction temperature is exceeded. When activated, typically at 165°C, the controller is forced into a low power reset state, disabling the output driver and the bias regulator. This protection is provided to prevent catastrophic failures from accidental device overheating.

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7.4 Device Functional Modes

Figure 10 shows how duty cycle effects the operational mode and is useful for reference in the following discussions. Initially, only the buck switch is active and the buck duty cycle increases to maintain output regulation as VIN decreases. When VIN is approximately equal to 15.5 V, the boost switch begins to operate with a low duty cycle. If VIN continues to fall, the boost switch duty cycle increases and the buck switch duty cycle decreases until they become equal at VIN = 13.2 V.

7.4.1 Buck Mode Operation: VIN > VOUT

The LM25118 buck-boost regulator operates as a conventional buck regulator with emulated current mode control while VIN is greater than VOUT and the buck mode duty cycle is less than 75%. In buck mode, the LO gate drive output to the boost switch remains low.

7.4.2 Buck-Boost Mode Operation: VIN ≅ VOUT

When VIN decreases relative to VOUT, the duty cycle of the buck switch will increase to maintain regulation. Once the duty cycle reaches 75%, the boost switch starts to operate with a very small duty cycle. As VIN is further decreased, the boost switch duty cycle increases until it is the same as the buck switch. As VIN is further decreased below VOUT, the buck and boost switch operate together with the same duty cycle and the regulator is in full buck-boost mode. This feature allows the regulator to transition smoothly from buck to buck-boost mode. Note that the regulator can be designed to operate with VIN less than 4 V, but VIN must be at least 5 V during start-up. Figure 16 shows a timing illustration of the gradual transition from buck to buck-boost mode when the input voltage ramps downward over a few switching cycles.

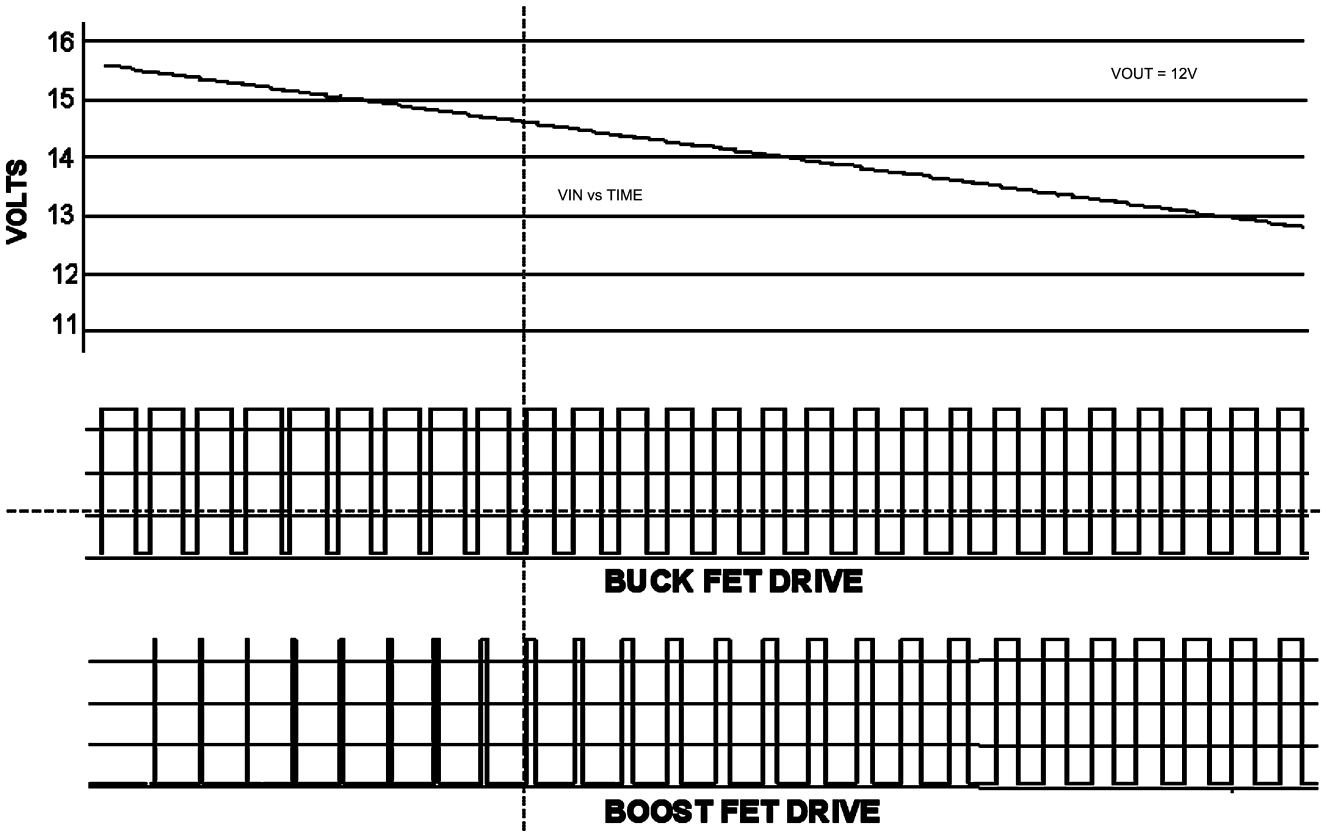


Figure 16. Buck (HO) and Boost (LO) Switch Duty Cycle vs. Time, Illustrating Gradual Mode Change With Decreasing Input Voltage

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Device Functional Modes (continued)

7.4.3 High Voltage Start-Up Regulator

The LM25118 contains a dual-mode, high voltage linear regulator that provides the VCC bias supply for the PWM controller and the MOSFET gate driver. The VIN input pin can be connected directly to input voltages as high as 42 V. For input voltages below 10 V, an internal low dropout switch connects VCC directly to VIN. In this supply range, VCC is approximately equal to VIN. For VIN voltages greater than 10 V, the low dropout switch is disabled and the VCC regulator is enabled to maintain VCC at approximately 7 V. A wide operating range of 4 V to 42 V (with a startup requirement of at least 5 V) is achieved through the use of this dual-mode regulator.

The output of the VCC regulator is current limited to 35 mA, typical. Upon power up, the regulator sources current into the capacitor connected to the VCC pin. When the voltage at the VCC pin exceeds the VCC under-voltage threshold of 3.7 V and the UVLO input pin voltage is greater than 1.23 V, the gate driver outputs are enabled and a soft-start sequence begins. The gate driver outputs remain enabled until VCC falls below 3.5 V or the voltage at the UVLO pin falls below 1.13 V.

In many applications, the regulated output voltage or an auxiliary supply voltage can be applied to the VCCX pin to reduce the IC power dissipation. For output voltages between 4 V and 15 V, VOUT can be connected directly to VCCX. When the voltage at the VCCX pin is greater than 3.85 V, the internal VCC regulator is disabled and an internal switch connects VCCX to VCC, reducing the internal power dissipation.

In high voltage applications, take extra care to ensure the VIN pin voltage does not exceed the absolute maximum voltage rating of 45 V. During line or load transients, voltage ringing on the VIN line that exceeds the absolute maximum rating can damage the IC. Both careful PCB layout and the use of quality bypass capacitors located close to the VIN and GND pins are essential.

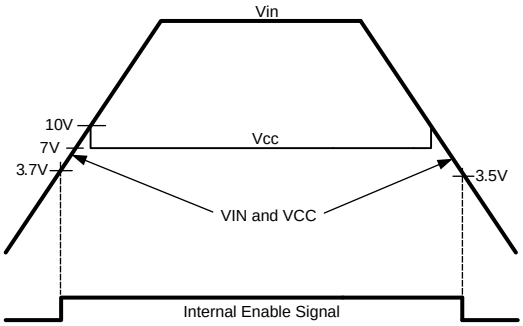


Figure 17. VIN and VCC Sequencing

7.4.4 Enable

The LM25118 contains an enable function which provides a very low input current shutdown mode. If the EN pin is pulled below 0.5 V, the regulator enters shutdown mode, drawing less than 10 µA from the VIN pin. Raising the EN input above 3 V returns the regulator to normal operation. The EN pin can be tied directly to the VIN pin if this function is not needed. It must not be left floating. A 1-MΩ pullup resistor to VIN can be used to interface with an open-collector or open-drain control signal.

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8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The LM25118 high voltage switching regulator features all of the functions necessary to implement an efficient high voltage buck or buck-boost regulator using a minimum of external components. A buckboost regulator can maintain regulation for input voltages either higher or lower than the output voltage.

8.2 Typical Application

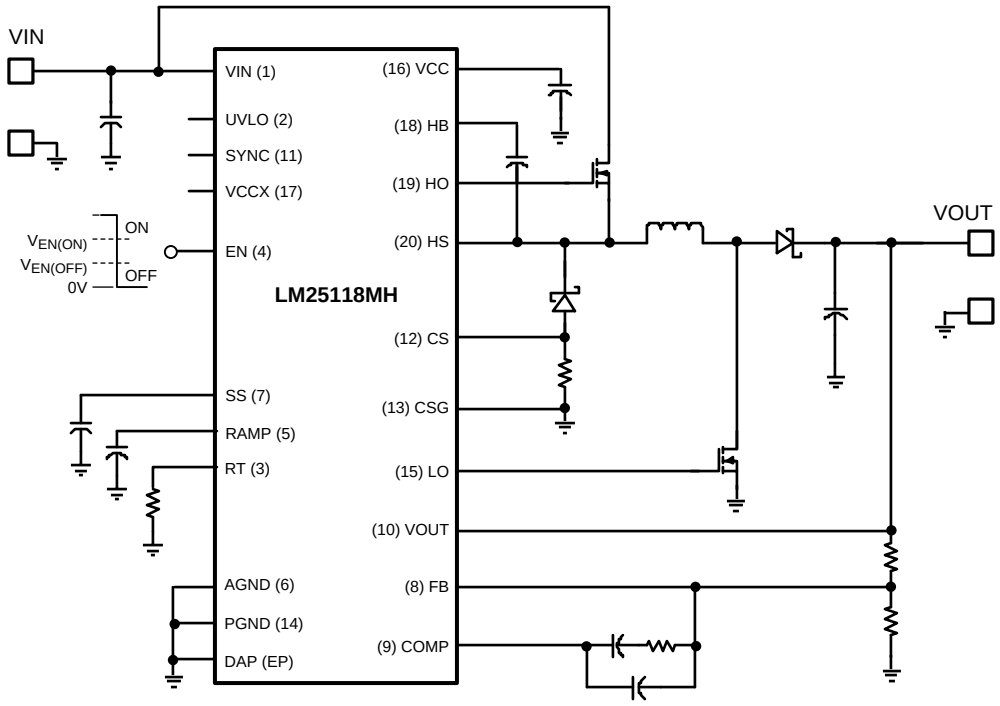


Figure 18. Typical Application Circuit

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Typical Application (continued)

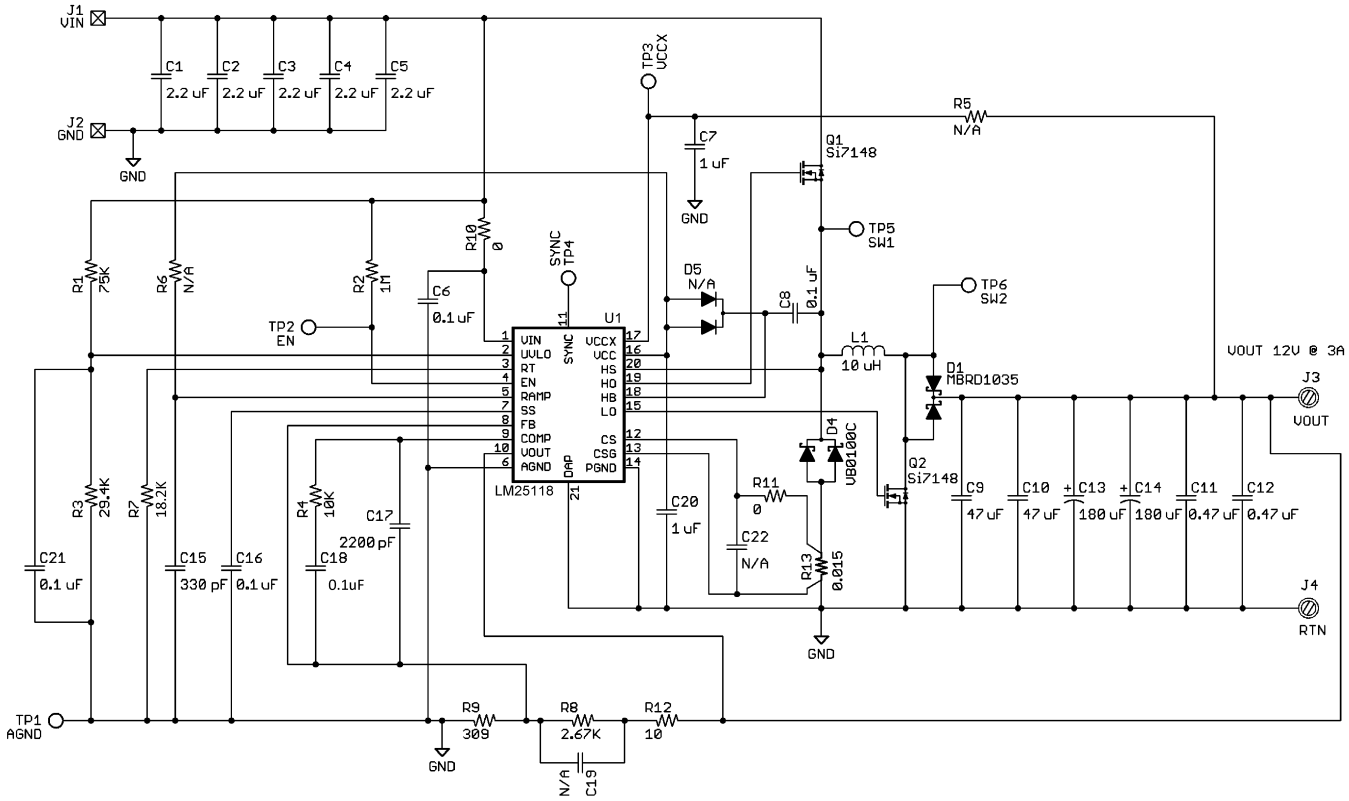


Figure 19. 12-V, 3-A Typical Application Schematic

8.2.1 Design Requirements

The procedure for calculating the external components is illustrated with the following design example. The designations used in the design example correlate to the Figure 19. The design specifications are:

- VOUT = 12 V
- VIN = 5 V to 42 V
- f = 300 kHz
- Minimum load current (CCM operation) = 600 mA
- Maximum load current = 3 A

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Typical Application (continued)

8.2.2 Detailed Design Procedure

8.2.2.1 Custom Design With WEBENCH® Tools

Click here to create a custom design using the LM25118 device with the WEBENCH® Power Designer.

1. Start by entering the input voltage (V_{IN}), output voltage (V_{OUT}), and output current (I_{OUT}) requirements.
2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at www.ti.com/WEBENCH.

8.2.2.2 R7 = R_T

RT sets the oscillator switching frequency. Generally speaking, higher operating frequency applications will use smaller components, but have higher switching losses. An operating frequency of 300 kHz was selected for this example as a reasonable compromise for both component size and efficiency. The value of R_T can be calculated as:

$$R_T = \frac{6.4 \times 10^9}{f} - 3.02 \times 10^3 \quad (9)$$

therefore, R7 = 18.3 kΩ

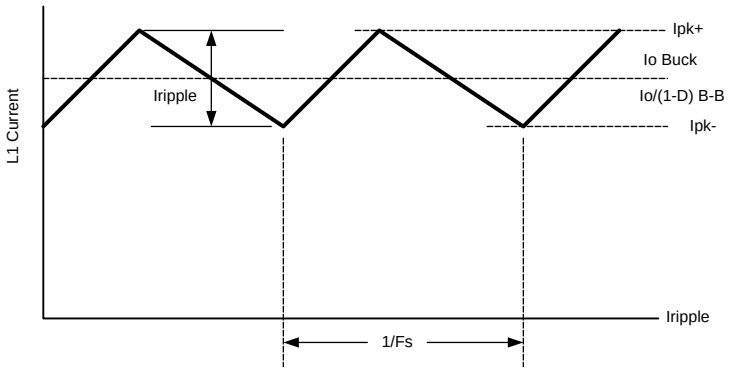


Figure 20. Inductor Current Waveform

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Typical Application (continued)

8.2.2.3 Inductor Selection – L1

The inductor value is determined based upon the operating frequency, load current, ripple current, and the input and output voltages. See Figure 20 for details.

To keep the circuit in continuous conduction mode (CCM), the maximum ripple current IRIPPLE should be less than twice the minimum load current. For the specified minimum load of 0.6 A, the maximum ripple current is 1.2 Ap-p. Also, the minimum value of L must be calculated both for a buck and buck-boost configurations. The final value of inductance will generally be a compromise between the two modes. It is desirable to have a larger value inductor for buck mode, but the saturation current rating for the inductor must be large for buck-boost mode, resulting in a physically large inductor. Additionally, large value inductors present buck-boost mode loop compensation challenges which will be discussed in *Error Amplifier Configuration* . For the design example, the inductor values in both modes are calculated as:

$$L1 = \frac{V_{OUT}(V_{IN(MAX)} - V_{OUT})}{V_{IN(MAX)} \times f \times I_{RIPPLE}} \text{ Buck Mode}$$

$$L1 = \frac{V_{IN(MIN)}(V_{OUT})}{(V_{OUT} + V_{IN(MIN)}) \times f \times I_{RIPPLE}} \text{ Buck-Boost Mode} \quad (10)$$

where

- V_{OUT} is the output voltage
- $V_{IN(MAX)}$ is the maximum input voltage
- f is the switching frequency
- I_{RIPPLE} is the selected inductor peak to peak ripple current (1.2 A selected for this example)
- $V_{IN(MIN)}$ is the minimum input voltage
- (11)

The resulting inductor values are:

L1 = 23.8 µH, Buck Mode (12)

L1 = 9.8 µH, Buck-Boost mode (13)

A 10-µH inductor was selected which is a compromise between these values, while favoring the buck-boost mode. As illustrated in the compensation section, the inductor value should be as low as possible to move the buck-boost right-half-plane zero to a higher frequency. The ripple current is then rechecked with the selected inductor value using Equation 10 and Equation 11.

$I_{RIPPLE(BUCK)}$ = 2.86 A (14)

$I_{RIPPLE(BUCK-BOOST)}$ = 1.17 A (15)

Because the inductor selected is lower than calculated for the Buck mode, the minimum load current for CCM in buck mode is 1.42 A at maximum VIN.

With a 10-µH inductor, the worst case peak inductor currents can be estimated for each case, assuming a 20% inductor value tolerance and 80% efficiency of the converter.

$$I_{1(PEAK)} = \frac{I_{OUT}}{\eta} + \frac{I_{RIPPLE(BUCK)}}{2(1 - L_{TOL})}$$

$$I_{2(PEAK)} = \frac{I_{OUT}(V_{OUT} + V_{IN(MIN)})}{\eta \times V_{IN(MIN)}} + \frac{I_{RIPPLE(BUCK-BOOST)}}{2(1 - L_{TOL})} \quad (16)$$

where

- η is efficiency
- L_{TOL} is the inductor tolerance (17)

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Typical Application (continued)

For this example, Equation 16 and Equation 17 yield:

$I_{1(PEAK)}$ = 5.33 A (18)

$I_{2(PEAK)}$ = 13.4 A (19)

An acceptable current limit setting would be 6.7 A for buck mode because the LM25118 automatically doubles the current limit threshold in buck-boost mode. The selected inductor must have a saturation current rating at least as high as the buck-boost mode cycle-by-cycle current limit threshold, in this case at least 13.5 A. A 10-µH, 15-A inductor was chosen for this application.

8.2.2.4 R13 = R_{SENSE}

To select the current sense resistor, begin by calculating the minimum K values for each mode using Equation 20 and Equation 21. K represents the slope compensation of the controller and is different for each mode, K_{BUCK} and $K_{BUCK-BOOST}$. K_{BUCK} and $K_{BUCK-BOOST}$ were selected to be 1.33 and 3, respectively.

$$K_{BUCK} \geq 1 + \frac{10}{V_{IN(MAX)} - V_{OUT}} \quad (20)$$

$$K_{BUCK-BOOST} \geq 1 + \frac{10}{V_{IN(MIN)}} \quad (21)$$

K_{BUCK} = 1.33 (22)

$K_{BUCK-BOOST}$ = 3 (23)

Use Equation 24 and Equation 25 to calculate R_{SENSE} for each mode of operation. A design margin, M, should be selected between 10%-30% to allow for component tolerances. For this design M was selected to be 10%.

$$R13_{(BUCK)} = \frac{1.25(1-M)}{10 \cdot \left(\frac{I_{OUT}}{\eta} + \frac{I_{RIPPLE(BUCK)}}{2} \cdot K_{BUCK} \right)} \quad (24)$$

$$R13_{(BUCK-BOOST)} = \frac{2.5 \cdot (1-M)}{10 \cdot \left(\frac{V_{IN(MIN)} + V_{OUT}}{V_{IN(MIN)}} \cdot \frac{I_{OUT}}{\eta} + \frac{I_{RIPPLE(BUCK-BOOST)}}{2} \cdot K_{BUCK-BOOST} \right)} \quad (25)$$

$R13_{(BUCK)}$ = 19.89 mΩ (26)

$R13_{(BUCK-BOOST)}$ = 15.5 mΩ (27)

An R_{SENSE} value of no more than 15.5 mΩ must be used to ensure the required maximum output current in the buck-boost mode. A standard value of 15 mΩ was selected for this design.

8.2.2.5 C15 = C_{RAMP}

With the inductor value selected, the value of C3 necessary for the emulation ramp circuit is:

$$C15 = C_{RAMP} = \frac{L \times 10^{-6}}{2 \times R_{SENSE}} \quad (28)$$

With the inductance value (L1) selected as 10 µH, the calculated value for C_{RAMP} is 333 pF. A standard value of 330 pF was selected.

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Typical Application (continued)

8.2.2.6 Inductor Current Limit Calculation

The current limit for each mode can be calculated using Equation 29 and Equation 31. If the peak current limit is less than the calculated inductor peak current, the R13 and C15 need to be recalculated. This can be done by increasing the previous K values or M and reiterating the calculations.

$$I_{LIMIT(BUCK)} = \frac{1.25 - \frac{50 \times 10^{-6} \times V_{OUT}}{C15 \times f \times V_{IN(MAX)}}}{10 \times R13} \quad (29)$$

$$I_{LIMIT\ (BUCK)} = 7.37\ A \quad (30)$$

$$I_{LIMIT(BUCK\text{-}BOOST)} = \frac{2.5 - \frac{50 \times 10^{-6} \times V_{OUT}}{C15 \times f \times (V_{IN(MIN)} + V_{OUT})}}{10 \times R13} \quad (31)$$

$$I_{LIMIT\ (BUCK\text{-}BOOST)} = 14.29\ A \quad (32)$$

8.2.2.7 C9 - C12 = Output Capacitors

In buck-boost mode, the output capacitors C9 – C12 must supply the entire output current during the switch on-time. For this reason, the output capacitors are chosen for operation in buck-boost mode, the demands being much less in buck operation. Both bulk capacitance and ESR must be considered to ensure a given output ripple voltage. Buck-boost mode capacitance can be estimated from:

$$C_{MIN} = \frac{I_{OUT} \times D_{MAX}}{f \times \Delta V_{OUT}} \text{ With } D_{MAX} = \frac{V_{OUT}}{V_{IN(MIN)} + V_{OUT}} \quad (33)$$

ESR requirements can be estimated from:

$$ESR_{MAX} = \frac{\Delta V_{OUT}}{\frac{V_{OUT} + V_{IN(MIN)}}{V_{IN(MIN)}} \cdot I_{OUT} + \frac{I_{RIPPLE(BUCK\text{-}BOOST)}}{2}} \quad (34)$$

For this example, with a ΔVOUT (output ripple) of 50 mV:

$$C_{MIN} = 141\ \mu F \quad (35)$$

$$ESR_{MAX} = 4.6\ m\Omega \quad (36)$$

If hold-up times are a consideration, the values of input and output capacitors must be increased appropriately. Note that it is usually advantageous to use multiple capacitors in parallel to achieve the ESR value required. Also, it is good practice to put a 0.1-µF to 0.47-µF ceramic capacitor directly on the output pins of the supply to reduce high-frequency noise. Ceramic capacitors have good ESR characteristics, and are a good choice for input and output capacitors. Note that the effective capacitance of ceramic capacitors decreases with DC bias. For larger bulk values of capacitance, a low-ESR electrolytic is usually used. However, electrolytic capacitors have poor tolerance, especially over temperature, and the selected value should be selected larger than the calculated value to allow for temperature variation. Allowing for component tolerances, the following values of Cout were chosen for this design example:

Two 180-µF Oscon electrolytic capacitors for bulk capacitance

Two 47-µF ceramic capacitors to reduce ESR

Two 0.47-µF ceramic capacitors to reduce spikes at the output

8.2.2.8 D1

Reverse recovery currents degrade performance and decrease efficiency. For these reasons, a Schottky diode of appropriate ratings should be used for D1. The voltage rating of the boost diode should be equal to VOUT plus some margin.

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Typical Application (continued)

8.2.2.9 D4

A Schottky type recirculating diode is required for all LM25118 applications. The near ideal reverse recovery characteristics and low forward voltage drop are particularly important diode characteristics for high input voltage and low output voltage applications. The reverse recovery characteristic determines how long the current surge lasts each cycle when the buck switch is turned on. The reverse recovery characteristics of Schottky diodes minimize the peak instantaneous power in the buck switch during the turn-on transition. The reverse breakdown rating of the diode should be selected for the maximum VIN plus some safety margin.

The forward voltage drop has a significant impact on the conversion efficiency, especially for applications with a low output voltage. *Rated* current for diodes vary widely from various manufacturers. For the LM25118 this current is user selectable through the current sense resistor value. Assuming a worst-case, 0.6-V drop across the diode, the maximum diode power dissipation can be high. The diode should have a voltage rating of VIN and a current rating of IOUT. A conservative design would at least double the advertised diode rating because specifications between manufacturers vary. For the reference design, a 100-V, 10-A Schottky in a D2PAK package was selected.

8.2.2.10 C1 – C5 = Input Capacitors

A typical regulator supply voltage has a large source impedance at the switching frequency. Good-quality input capacitors are necessary to limit the ripple voltage at the VIN pin while supplying most of the switch current during the buck switch on-time. When the buck switch turns on, the current into the buck switch steps from zero to the lower peak of the inductor current waveform, then ramps up to the peak value, and then drops to the zero at turnoff. The RMS current rating of the input capacitors depends on which mode of operation is most critical.

$$I_{RMS(BUCK)} = I_{OUT} \sqrt{D(1 - D)} \tag{37}$$

The RMS current demand on the input capacitor(s) is at the maximum value when the duty cycle is at 50%.

$$I_{RMS(BUCK\text{-}BOOST)} = \frac{I_{OUT}}{1 - D} \sqrt{D(1 - D)} \tag{38}$$

Checking both modes of operation we find:

$$I_{RMS(BUCK)} = 1.5 \text{ A} \tag{39}$$

$$I_{RMS(BUCK\text{-}BOOST)} = 4.7 \text{ A} \tag{40}$$

Therefore C1 — C5 should be sized to handle 4.7 A of ripple current. Quality ceramic capacitors with a low ESR should be selected. To allow for capacitor tolerances, five 2.2-µF, 100-V ceramic capacitors will be used. If step input voltage transients are expected near the maximum rating of the LM25118, a careful evaluation of the ringing and possible spikes at the device VIN pin should be completed. An additional damping network or input voltage clamp may be required in these cases.

8.2.2.11 C20

The capacitor at the VCC pin provides noise filtering and stability for the VCC regulator. The recommended value of C20 should be no smaller than 0.1 µF, and should be a good-quality, low-ESR, ceramic capacitor. A value of 1 µF was selected for this design. C20 should be 10 x C8.

If operating without VCCX, then

$$f_{OSC} \times (Q_C\text{Buck + Boost}) + I_{LOAD(INTERNAL)} \tag{41}$$

must be less than the VCC current limit.

8.2.2.12 C8

The bootstrap capacitor between the HB and HS pins supplies the gate current to charge the buck switch gate at turnon. The recommended value of C8 is 0.1 µF to 0.47 µF, and should be a good-quality, low-ESR, ceramic capacitor. A value of 0.1 µF was chosen for this design.

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Typical Application (continued)

8.2.2.13 C16 = C_{SS}

The capacitor at the SS pin determines the soft-start time, that is, the time for the reference voltage and the output voltage, to reach the final regulated value. The time is determined from:

$$t_{SS} = \frac{C16 \times 1.23V}{10\ \mu A} \tag{42}$$

and assumes a current limit>Iload + ICout

For this application, a C16 value of 0.1 µF was chosen which corresponds to a soft-start time of about 12 ms.

8.2.2.14 R8, R9

R8 and R9 set the output voltage level, the ratio of these resistors is calculated from:

$$\frac{R8}{R9} = \frac{V_{OUT}}{1.23V} - 1 \tag{43}$$

For a 12-V output, the R8/R9 ratio calculates to 8.76. The resistors should be chosen from standard value resistors and a good starting point is to select resistors within power ratings appropriate for the output voltage. Values of 309 Ω for R9 and 2.67 kΩ for R8 were selected.

8.2.2.15 R1, R3, C21

A voltage divider can be connected to the UVLO pin to set a minimum operating voltage $VIN_{(UVLO)}$ for the regulator. If this feature is required, the easiest approach to select the divider resistor values is to choose a value for R1 between 10 kΩ and 100 kΩ, while observing the minimum value of R1 necessary to allow the UVLO switch to pull the UVLO pin low. This value is:

$R1 \geq 1000 \times V_{IN(MAX)}$

R1 ≥ 75 k

R3 is then calculated from:

$$R3 = 1.23 \times \left[\frac{R1}{V_{IN(MIN)} + 5\ \mu A \times R1 - 1.23} \right] \tag{44}$$

Because $VIN_{(MIN)}$ for our example is 5 V, set $VIN_{(UVLO)}$ to 4 V for some margin in component tolerances and input ripple.

R1 = 75 k is chosen because it is a standard value

R3 = 29.332 k is calculated from Equation 44. 29.4 k was used because it is a standard value

Capacitor C21 provides filtering for the divider and the off time of the *hiccup* duty cycle during current limit. The voltage at the UVLO pin should never exceed 15 V when using an external set-point divider. It may be necessary to clamp the UVLO pin at high input voltages.

Knowing the desired off time during *hiccup* current limit, the value of C21 is given by:

$$t_{OFF} = \frac{-C21 \cdot R1 \cdot R3}{R1 + R3} \cdot Ln\left[1 - .98 \cdot \frac{R1 + R3}{V_{IN} \cdot R3}\right] \tag{45}$$

Notice that t_{OFF} varies with V_{IN}

In this example, C21 was chosen to be 0.1 µF. This will set the t_{OFF} time to 723 µs with VIN = 12 V.

8.2.2.16 R2

A 1-M pullup resistor connected from the EN pin to the VIN pin is sufficient to keep enable in a high state if on-off control is not used.

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Typical Application (continued)

8.2.2.17 Snubber

A snubber network across the buck recirculating diode reduces ringing and spikes at the switching node. Excessive ringing and spikes can cause erratic operation and increase noise at the regulator output. In the limit, spikes beyond the maximum voltage rating of the LM25118 or the recirculating diode can damage these devices. Selecting the values for the snubber is best accomplished through empirical methods. First, make sure the lead lengths for the snubber connections are very short. Start with a resistor value between 5 and 20 Ω. Increasing the value of the snubber capacitor results in more damping, however the snubber losses increase. Select a minimum value of the capacitor that provides adequate clamping of the diode waveform at maximum load. A snubber may be required for the boost diode as well. The same empirical procedure applies. Snubbers were not necessary in this example.

8.2.2.18 Error Amplifier Configuration

8.2.2.18.1 R4, C18, C17

These components configure the error amplifier gain characteristics to accomplish a stable overall loop gain. One advantage of current mode control is the ability to close the loop with only three feedback components, R4, C18, and C17. The overall loop gain is the product of the modulator gain and the error amplifier gain. The DC modulator gain of the LM25118 is as follows:

$$DCGain_{(MOD)} = \frac{R_{LOAD} \times V_{IN}}{10R_S(V_{IN} + 2V_{OUT})} \quad (46)$$

The dominant, low frequency pole of the modulator is determined by the load resistance (R_{LOAD}) and output capacitance (C_{OUT}). The corner frequency of this pole is:

$$f_{P(MOD)} = \frac{1+D_{MAX}}{2\pi \times R_{LOAD} \times C_{OUT}} \quad (47)$$

For this example, R_{LOAD} = 4 Ω, D_{MAX} = 0.705, and C_{OUT} = 454 µF, therefore:

$$f_{P(MOD)} = 149 \text{ Hz} \quad (48)$$

$$DC\ Gain_{(MOD)} = 4.59 = 13.25 \text{ dB} \quad (49)$$

Additionally, there is a right-half plane (RHP) zero associated with the modulator. The frequency of the RHP zero is:

$$f_{RHPzero} = \frac{R_{LOAD}\ (1 - D)^2}{2\pi \text{ x } L \text{ x } D} \quad (50)$$

$$f_{RHPzero} = 7.8 \text{ kHz} \quad (51)$$

The output capacitor ESR produces a zero given by:

$$ESR_{zero} = \frac{1}{2\pi \text{ x } ESR \text{ x } C_{OUT}} \quad (52)$$

$$ESR_{ZERO} = 76 \text{ kHz} \quad (53)$$

The RHP zero complicates compensation. The best design approach is to reduce the loop gain to cross zero at about 25% of the calculated RHP zero frequency. The Type II error amplifier compensation provided by R4, C18, and C17 places one pole at the origin for high DC gain. The second pole should be placed close to the RHP zero. The error amplifier zero (Equation 54) should be placed near the dominate modulator pole. This is a good starting point for compensation.

Components R4 and C18 configure the error amplifier as a Type II configuration which has a DC pole and a zero at

$$f_z = \frac{1}{2 \text{ x } \pi \text{ x } R4 \text{ x } C18} \quad (54)$$

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Typical Application (continued)

C17 introduces an additional pole used to cancel high frequency switching noise. The error amplifier zero cancels the modulator pole leaving a single pose response at the crossover frequency of the loop gain if the crossover frequency is much lower than the right half plane zero frequency. A single pole response at the crossover frequency yields a very stable loop with 90 degrees of phase margin.

For the design example, a target loop bandwidth (crossover frequency) of 2.0 kHz was selected (about 25% of the right-half-plane zero frequency). The error amplifier zero (fz) should be selected at a frequency near that of the modulator pole and much less than the target crossover frequency. This constrains the product of R4 and C18 for a desired compensation network zero to be less than 2 kHz. Increasing R4, while proportionally decreasing C18 increases the error amp gain. Conversely, decreasing R4 while proportionally increasing C18 decreases the error amp gain. For the design example C18 was selected for 100 nF and R4 was selected to be 10 kΩ. These values set the compensation network zero at 159 Hz. The overall loop gain can be predicted as the sum (in dB) of the modulator gain and the error amp gain.

If a network analyzer is available, the modulator gain can be measured and the error amplifier gain can be configured for the desired loop transfer function. If a network analyzer is not available, the error amplifier compensation components can be designed with the guidelines given. Step load transient tests can be performed to verify acceptable performance. The step load goal is minimal overshoot with a damped response.

Please see the plots shown in Figure 21 through Figure 26 which illustrate the gain and phase diagrams of the design example.

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Typical Application (continued)

8.2.3 Application Curves

The plots shown in Figure 21 through Figure 26 show the gain and phase diagrams of the design example. The overall bandwidth is lower in a buck-boost application due the compensation challenges associated with the right-half-plane zero. For a pure buck application, the bandwidth could be much higher. The LM5116 data sheet is a good reference for compensation design of a pure buck mode regulator.

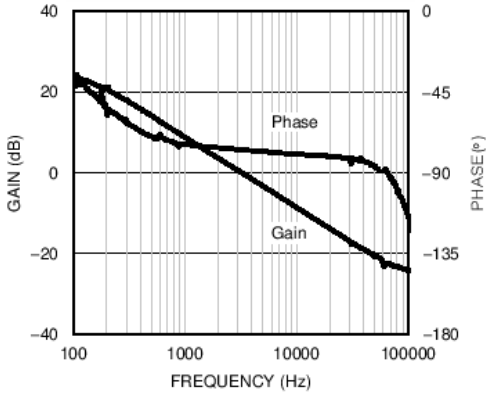


Figure 21. Modulator Gain and Phase - Buck Mode

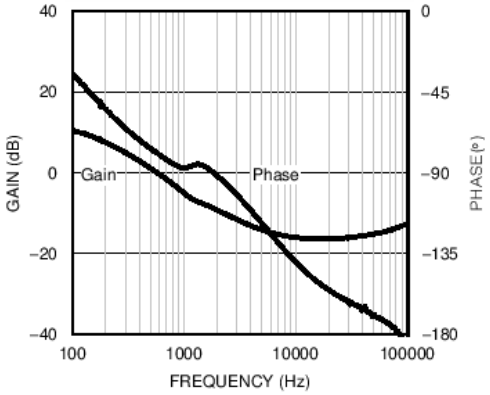


Figure 22. Modulator Gain and Phase - Buck-Boost Mode

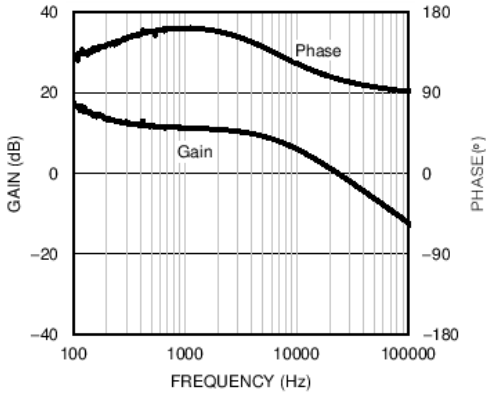


Figure 23. Error Amplifier Gain and Phase - Buck Mode

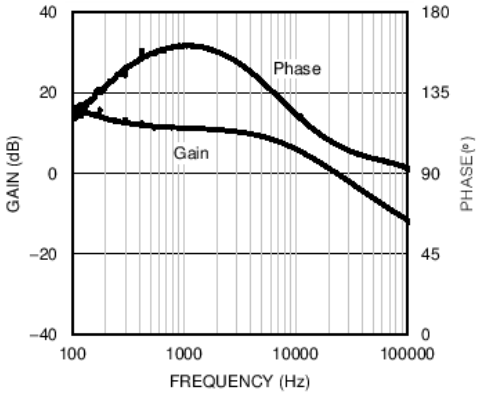


Figure 24. Error Amplifier Gain and Phase - Buck-Boost Mode

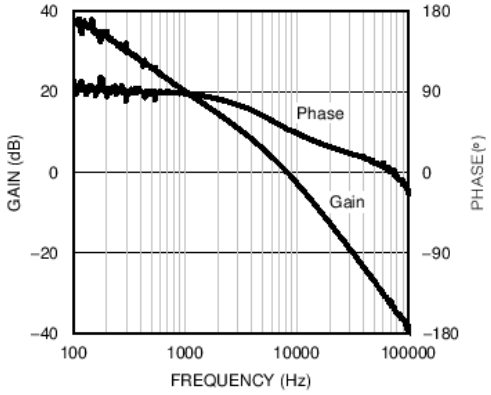


Figure 25. Overall Loop Gain and Phase - Buck Mode

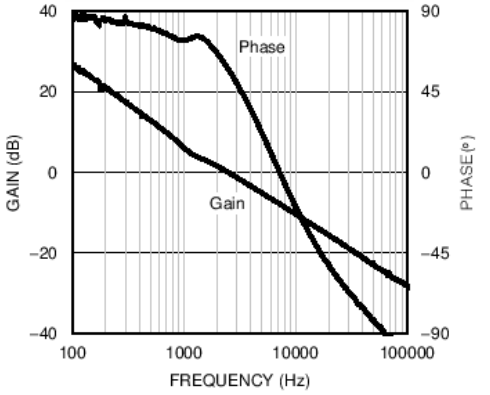


Figure 26. Overall Loop Gain and Phase - Buck-Boost Mode

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9 Power Supply Recommendations

9.1 Bias Power Dissipation Reduction

Buck or Buck-boost regulators operating with high-input voltage can dissipate an appreciable amount of power while supplying the required bias current of the IC. The VCC regulator must step-down the input voltage VIN to a nominal VCC level of 7 V. The large voltage drop across the VCC regulator translates into high power dissipation in the VCC regulator. There are several techniques that can significantly reduce this bias regulator power dissipation. Figure 27 and Figure 28 depict two methods to bias the IC, one from the output voltage and one from a separate bias supply. In the first case, the internal VCC regulator is used to initially bias the VCC pin. After the output voltage is established, the VCC pin bias current is supplied through the VCCX pin, which effectively disables the internal VCC regulator. Any voltage greater than 4 V can supply VCC bias through the VCCX pin. However, the voltage applied to the VCCX pin should never exceed 15 V. The voltage applied to the VCCX pin should never exceed 15 V. The voltage supplied through VCCX must be large enough to drive the switching MOSFETs into full saturation.

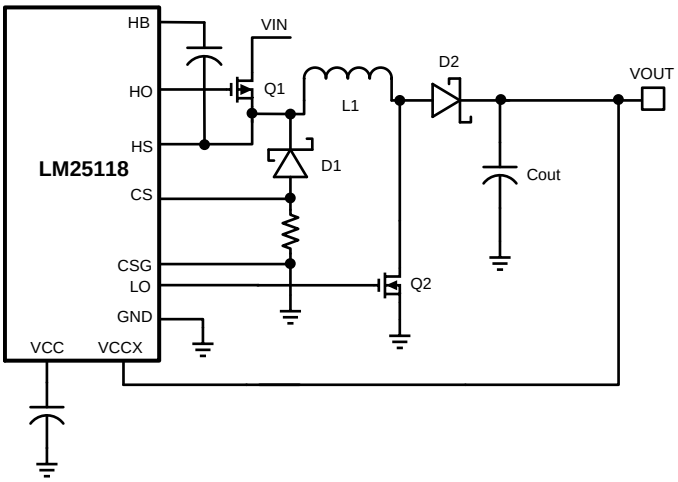


Figure 27. VCC Bias From VOUT 4 V < VOUT < 15 V

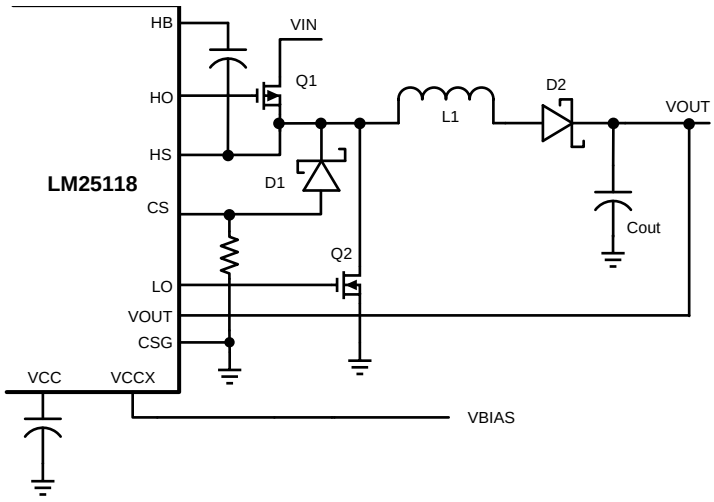


Figure 28. VCC Bias With Additional Bias Supply

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9.2 Thermal Considerations

The highest power dissipating components are the two power MOSFETs, the recirculating diode, and the output diode. The easiest way to determine the power dissipated in the MOSFETs is to measure the total conversion losses (P_{IN} - P_{OUT}), then subtract the power losses in the Schottky diodes, output inductor and any snubber resistors. An approximation for the recirculating Schottky diode loss is:

$$P = (1\text{-}D) \times I_{OUT} \times V_{FWD} \quad (55)$$

The boost diode loss is:

$$P = I_{OUT} \times V_{FWD} \quad (56)$$

If a snubber is used, the power loss can be estimated with an oscilloscope by observation of the resistor voltage drop at both turnon and turnoff transitions. The LM25118 package has an exposed thermal pad to aid power dissipation. Selecting diodes with exposed pads will aid the power dissipation of the diodes as well. When selecting the MOSFETs, pay careful attention to $R_{DS(ON)}$ at high temperature. Also, selecting MOSFETs with low gate charge will result in lower switching losses.

See Application Notes *AN-1520 A Guide to Board Layout for Best Thermal Resistance for Exposed Packages* (SNVA183) and *AN-2020 Thermal Design By Insight, Not Hindsight* (SNVA419) for thermal management techniques for use with surface mount components.

10 Layout

10.1 Layout Guidelines

In a buck-boost regulator, there are two loops where currents are switched very fast. The first loop starts from the input capacitors, and then to the buck switch, the inductor, the boost switch then back to the input capacitor. The second loop starts from the inductor, and then to the output diode, the output capacitor, the recirculating diode, and back to the inductor. Minimizing the PCB area of these two loops reduces the stray inductance and minimizes noise and the possibility of erratic operation. A ground plane in the PCB is recommended as a means to connect the input filter capacitors to the output filter capacitors and the PGND pins of the LM25118. Connect all of the low current ground connections (C_{SS}, R_T, C_{RAMP}) directly to the regulator AGND pin. Connect the AGND and PGND pins together through topside copper area covering the entire underside of the device. Place several vias in this underside copper area to the ground plane of the input capacitors.

10.2 Layout Example

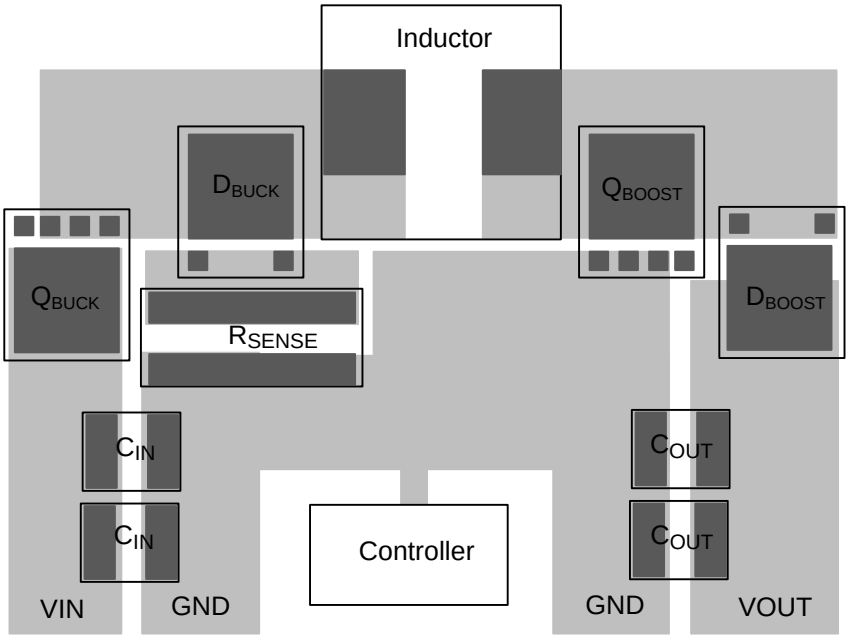


Figure 29. LM25118 Layout Example

11 デバイスおよびドキュメントのサポート

11.1 デバイス・サポート

11.1.1 開発サポート

11.1.1.1 WEBENCH®ツールによるカスタム設計

ここをクリックすると、WEBENCH® Power Designerにより、LM25118デバイスを使用するカスタム設計を作成できます。

1. 最初に、入力電圧(V_{IN})、出力電圧(V_{OUT})、出力電流(I_{OUT})の要件を入力します。
2. オプティマイザのダイヤルを使用して、効率、占有面積、コストなどの主要なパラメータについて設計を最適化します。
3. 生成された設計を、テキサス・インスツルメンツが提供する他のソリューションと比較します。

WEBENCH Power Designerでは、カスタマイズされた回路図と部品リストを、リアルタイムの価格と部品の在庫情報と併せて参照できます。

ほとんどの場合、次の操作を実行可能です。

- 電気的なシミュレーションを実行し、重要な波形と回路の性能を確認する。
- 熱シミュレーションを実行し、基板の熱特性を把握する。
- カスタマイズされた回路図やレイアウトを、一般的なCADフォーマットでエクスポートする。
- 設計のレポートをPDFで印刷し、同僚と設計を共有する。

WEBENCHツールの詳細は、www.ti.com/WEBENCHでご覧になれます。

11.2 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、ti.comのデバイス製品フォルダを開いてください。右上の隅にある「*通知を受け取る*」をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取れます。変更の詳細については、修正されたドキュメントに含まれている改訂履歴をご覧ください。

11.3 コミュニティ・リソース

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

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11.6 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

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12 メカニカル、パッケージ、および注文情報

以降のページには、メカニカル、パッケージ、および注文に関する情報が記載されています。この情報は、そのデバイスについて利用可能な最新のデータです。このデータは予告なく変更されることがあり、ドキュメントが改訂される場合もあります。本データシートのブラウザ版を使用されている場合は、画面左側の説明をご覧ください。

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM25118MH/NOPB	Active	Production	HTSSOP (PWP) | 20	73 | TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LM25118 MH
LM25118MH/NOPB.A	Active	Production	HTSSOP (PWP) | 20	73 | TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LM25118 MH
LM25118MH/NOPB.B	Active	Production	HTSSOP (PWP) | 20	73 | TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LM25118 MH
LM25118MHE/NOPB	Active	Production	HTSSOP (PWP) | 20	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LM25118 MH
LM25118MHE/NOPB.A	Active	Production	HTSSOP (PWP) | 20	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LM25118 MH
LM25118MHE/NOPB.B	Active	Production	HTSSOP (PWP) | 20	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LM25118 MH
LM25118MHX/NOPB	Active	Production	HTSSOP (PWP) | 20	2500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LM25118 MH
LM25118MHX/NOPB.A	Active	Production	HTSSOP (PWP) | 20	2500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LM25118 MH
LM25118MHX/NOPB.B	Active	Production	HTSSOP (PWP) | 20	2500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	LM25118 MH

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF LM25118 :

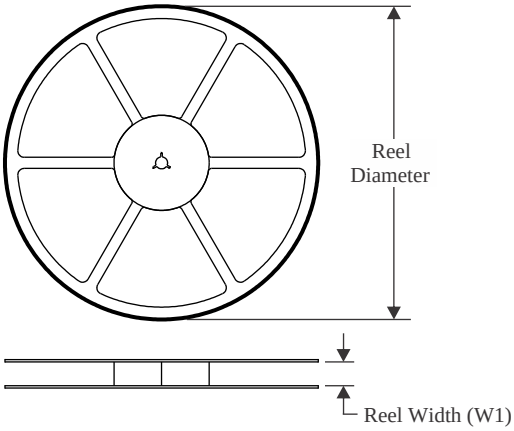
- Automotive : LM25118-Q1

NOTE: Qualified Version Definitions:

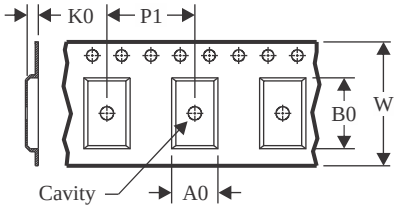
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION

REEL DIMENSIONS

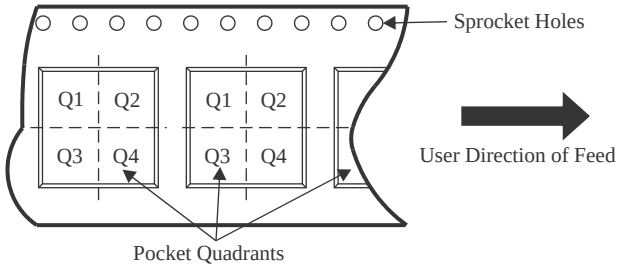


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

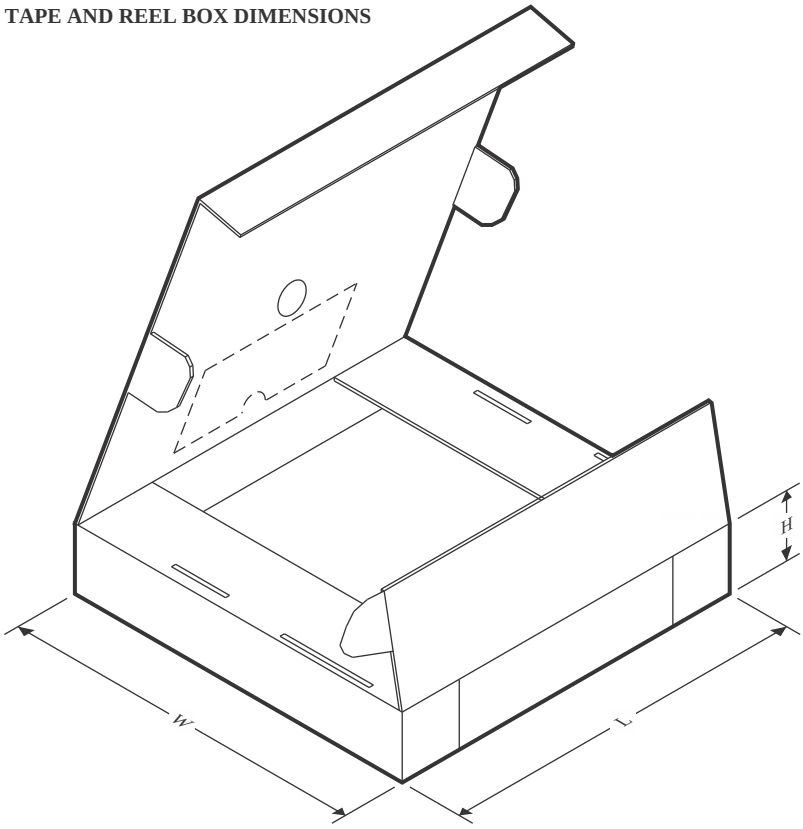
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM25118MHE/NOPB	HTSSOP	PWP	20	250	178.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
LM25118MHX/NOPB	HTSSOP	PWP	20	2500	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1

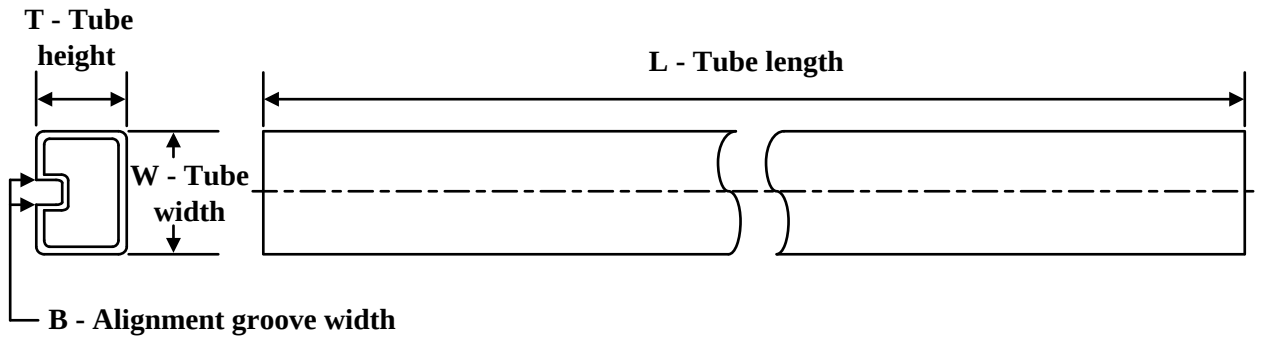
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

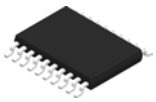
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM25118MHE/NOPB	HTSSOP	PWP	20	250	210.0	185.0	35.0
LM25118MHX/NOPB	HTSSOP	PWP	20	2500	367.0	367.0	35.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
LM25118MH/NOPB	PWP	HTSSOP	20	73	495	8	2514.6	4.06
LM25118MH/NOPB.A	PWP	HTSSOP	20	73	495	8	2514.6	4.06
LM25118MH/NOPB.B	PWP	HTSSOP	20	73	495	8	2514.6	4.06

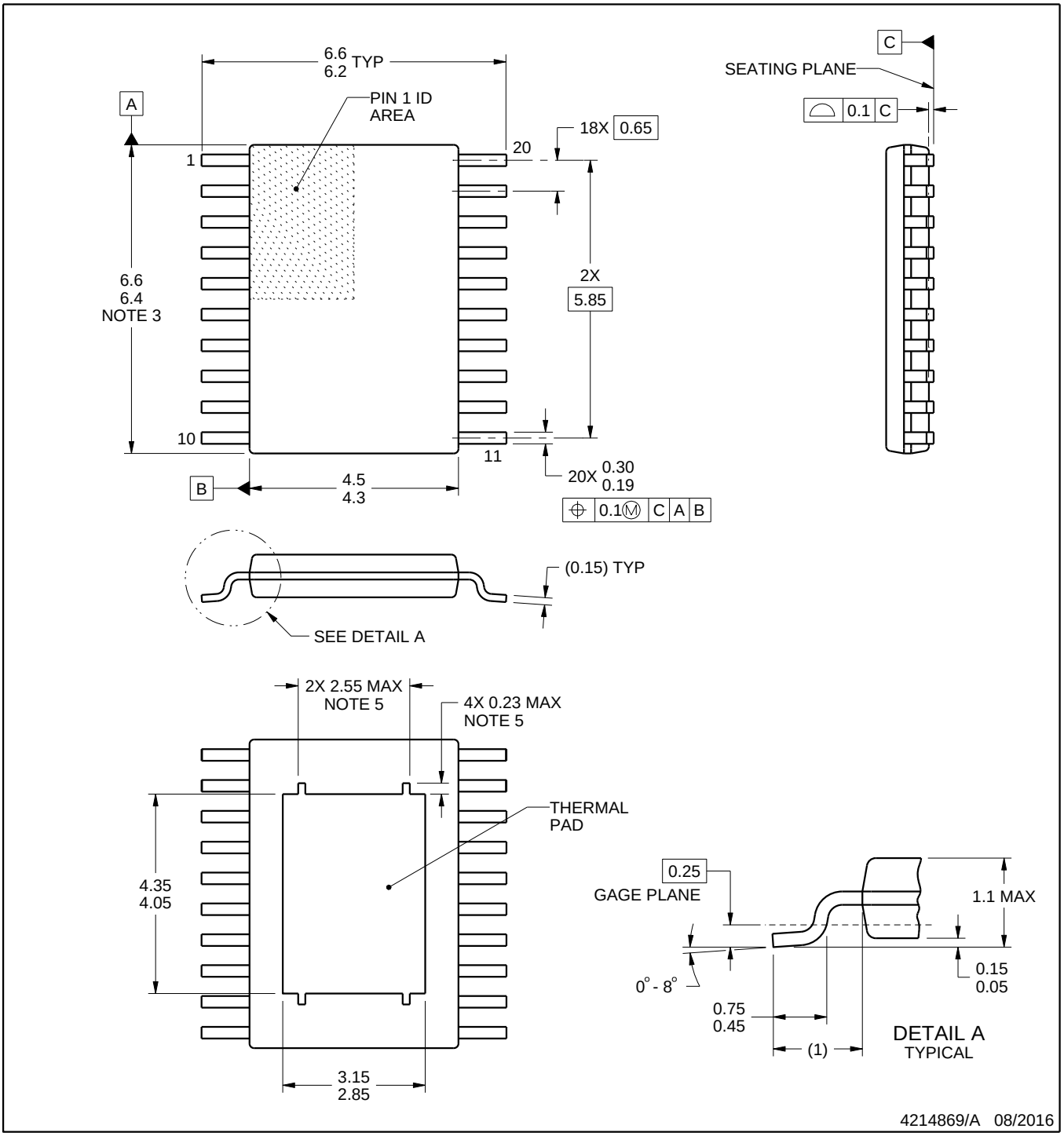


PACKAGE OUTLINE

PWP0020A

PowerPAD™ TSSOP - 1.1 mm max height

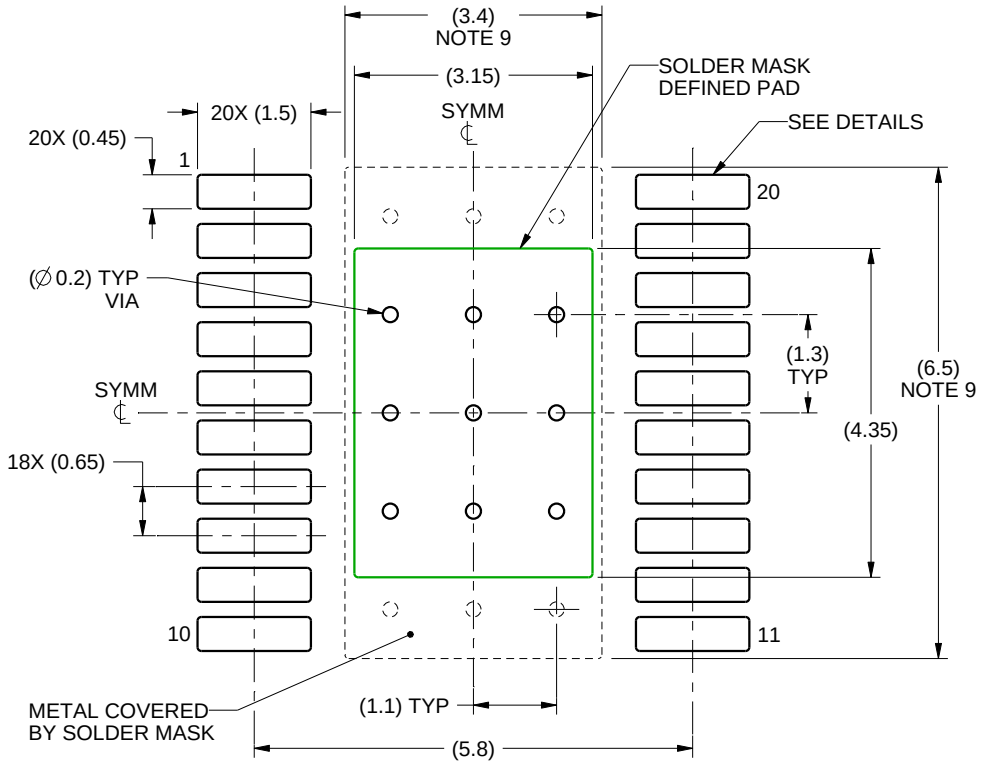
PLASTIC SMALL OUTLINE



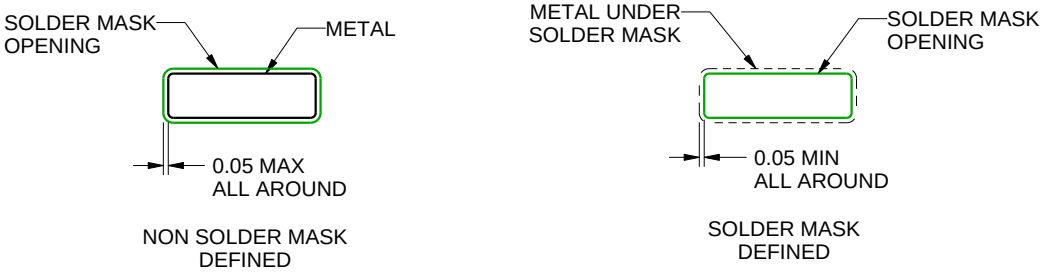
PowerPAD is a trademark of Texas Instruments.

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-153.
5. Features may differ or may not be present.



LAND PATTERN EXAMPLE
SCALE:10X

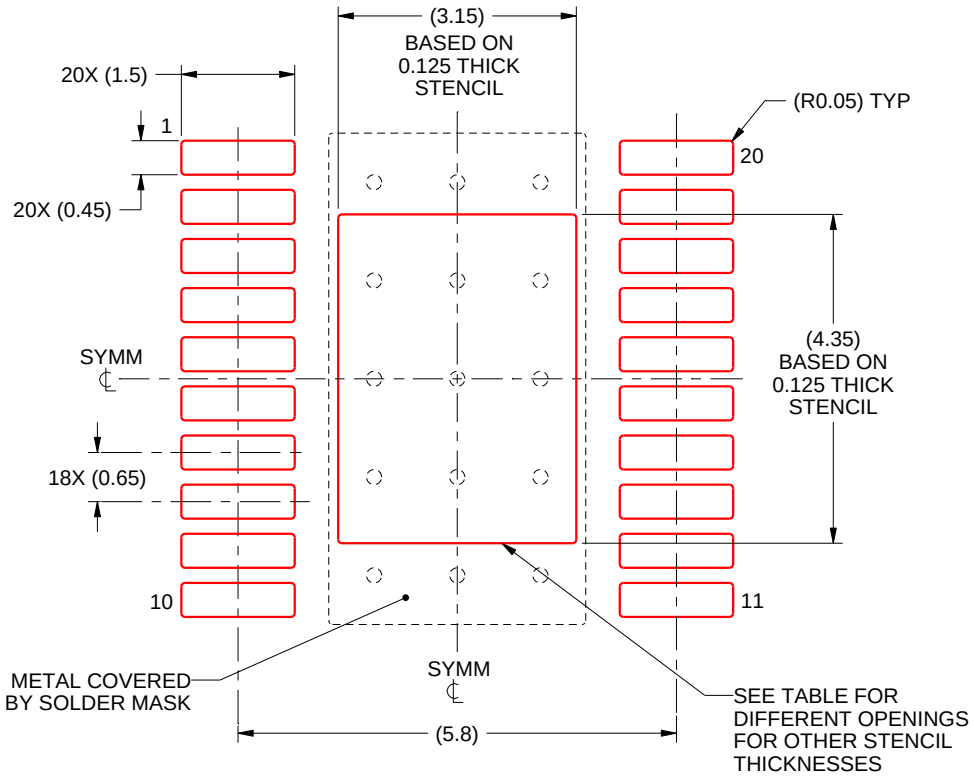


SOLDER MASK DETAILS
PADS 1-20

4214869/A 08/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 (www.ti.com/lit/slma002) and SLMA004 (www.ti.com/lit/slma004).
9. Size of metal pad may vary due to creepage requirement.



SOLDER PASTE EXAMPLE
EXPOSED PAD
100% PRINTED SOLDER COVERAGE BY AREA
SCALE:10X

STENCIL THICKNESS	SOLDER STENCIL OPENING
0.1	3.52 X 4.86
0.125	3.15 X 4.35 (SHOWN)
0.15	2.88 X 3.97
0.175	2.66 X 3.68

4214869/A 08/2016

NOTES: (continued)

10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
11. Board assembly site may have different recommendations for stencil design.

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最終更新日：2025 年 10 月